

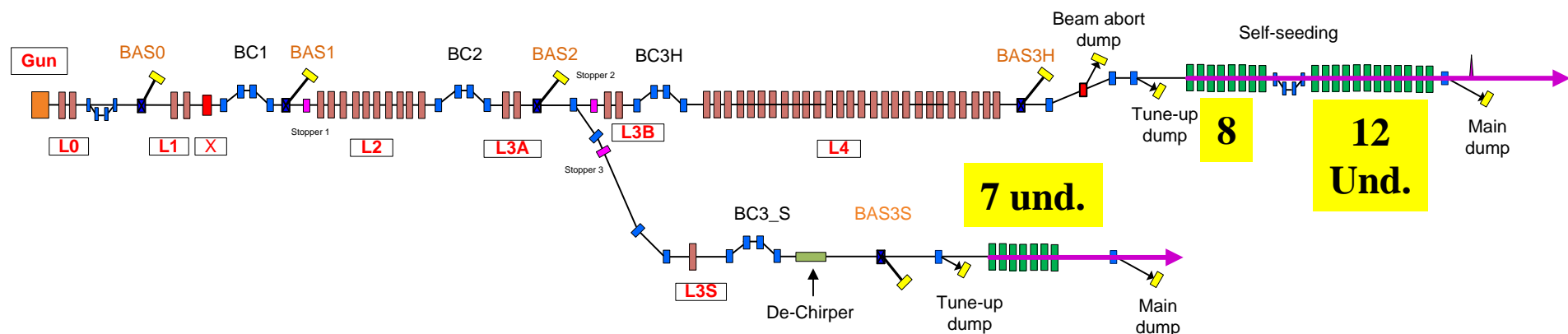
Undulator BBA & FEL Commissioning for PAL-XFEL

Heung-Sik Kang

on behalf of PAL-XFEL team

Pohang Accelerator Laboratory

PAL-XFEL Layout

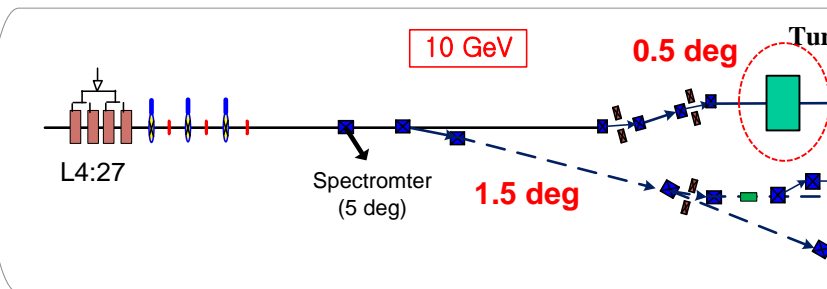
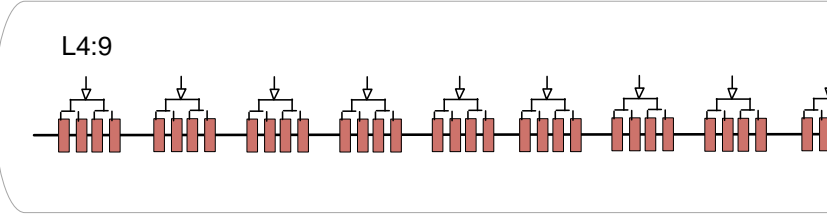
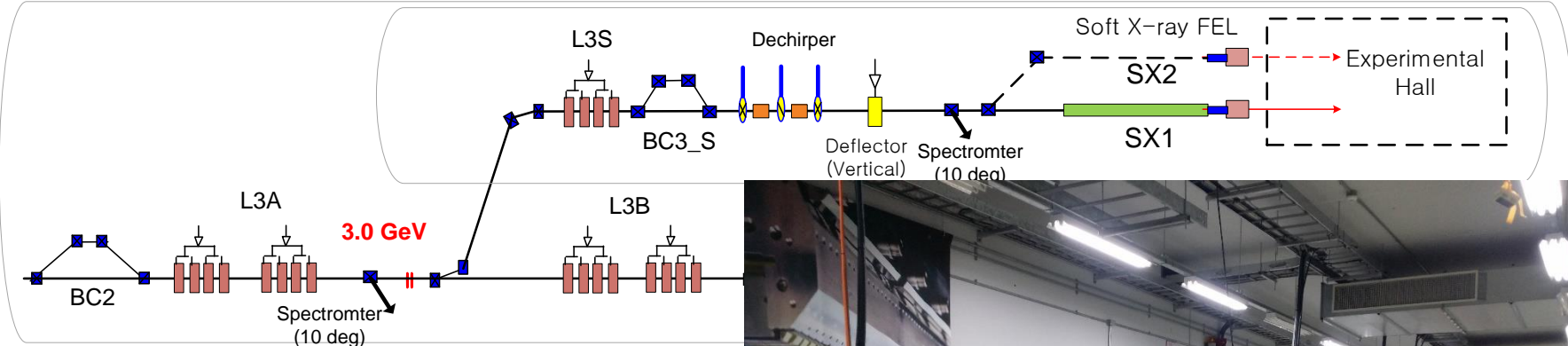
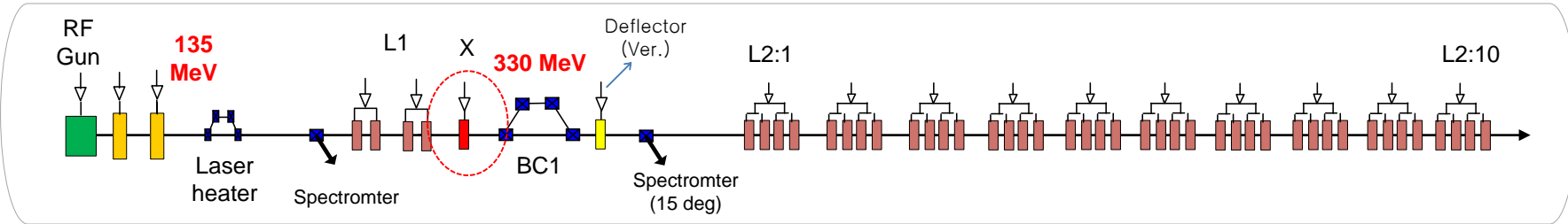


Main parameters

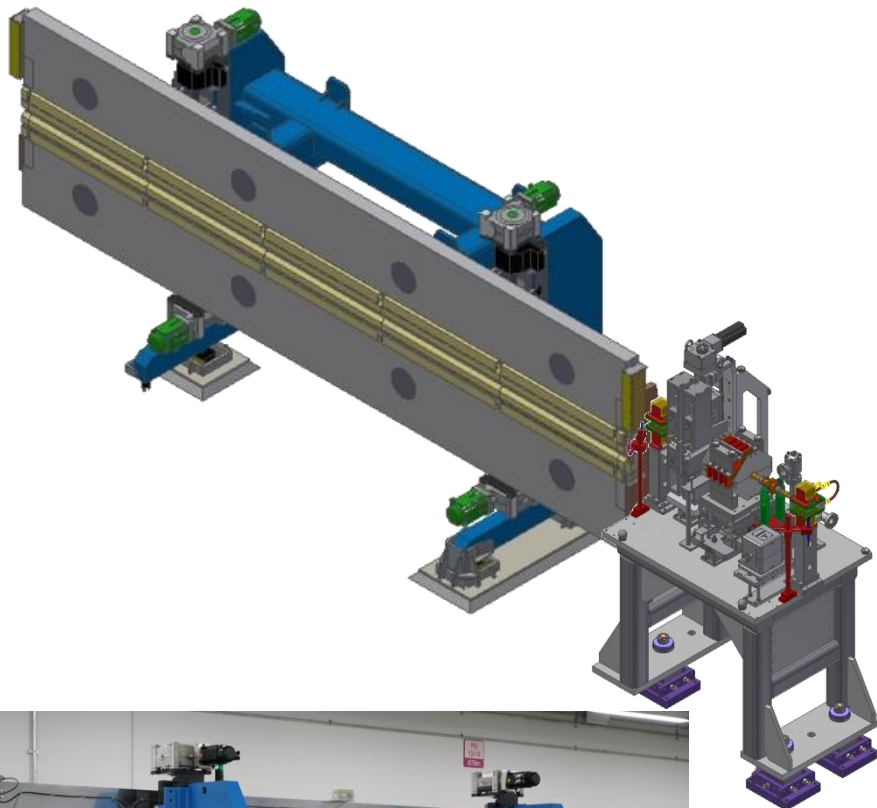
e ⁻ Energy	10 GeV
e ⁻ Bunch charge	20-200 pC
Slice emittance	0.5 mm mrad
Repetition rate	60 Hz
Pulse duration	5 fs – 100 fs
Peak current	3 kA
SX line switching	DC (Phase-1) Kicker (Phase-2)

Undulator Line	HX1	SX1
Wavelength [nm]	0.1 ~ 0.6	1 ~ 4.5
Beam Energy [GeV]	4 ~ 10	3.15
Wavelength Tuning [nm]	0.6 ~ 0.1 (energy or gap)	4.5 ~ 3 (energy) 3 ~ 1 (gap)
Undulator Type	Planar, out-vac.	Planar, out-vac
Undulator Period / Gap [mm]	26 / 8.3	35 / 8.3

PAL-XFEL Layout (Detail)



Undulator

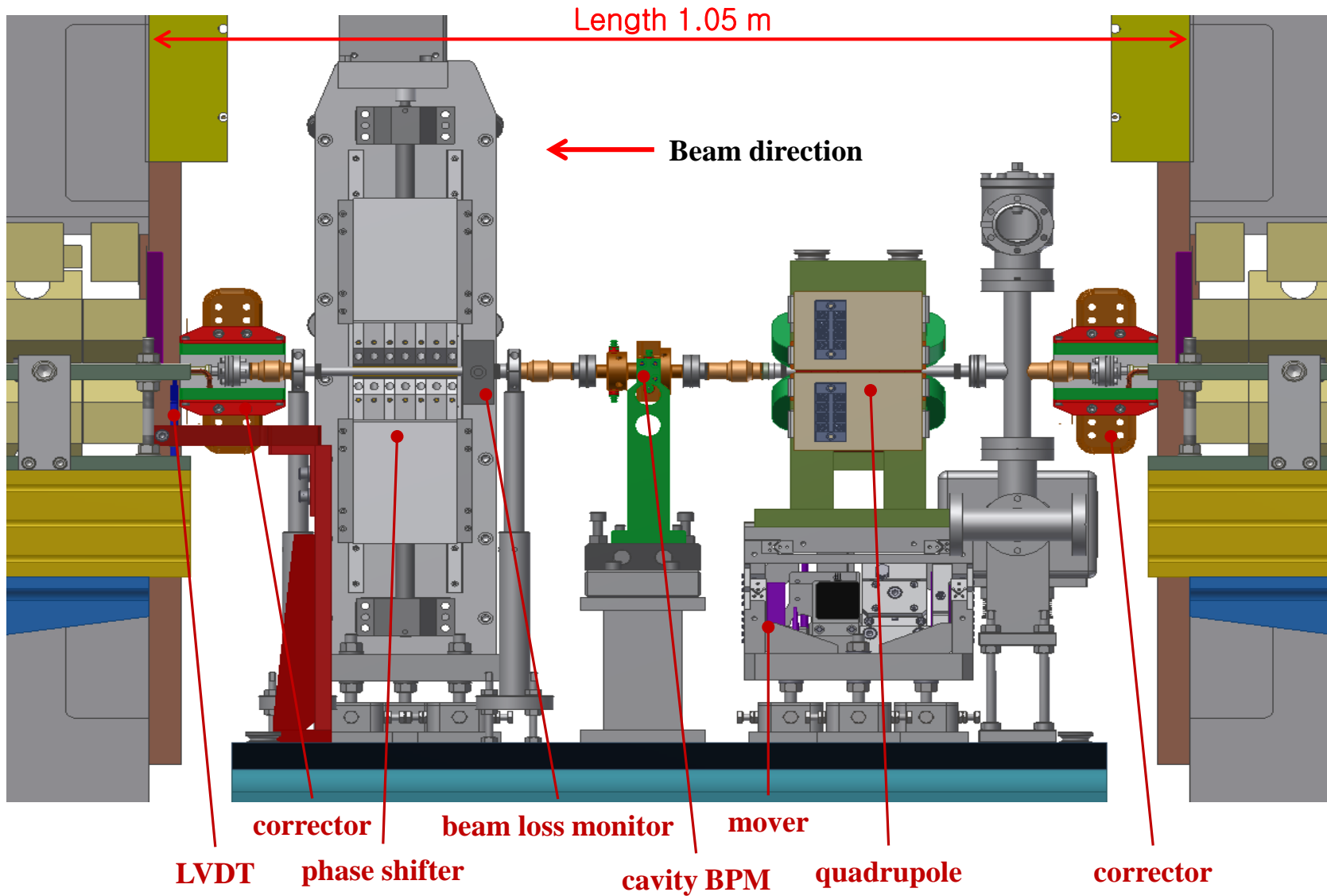


- EU-XFEL undulator design is benchmarked.
- PAL modified the design including the new magnetic design, EPICS IOC, and updated tolerances reflecting new parameters.

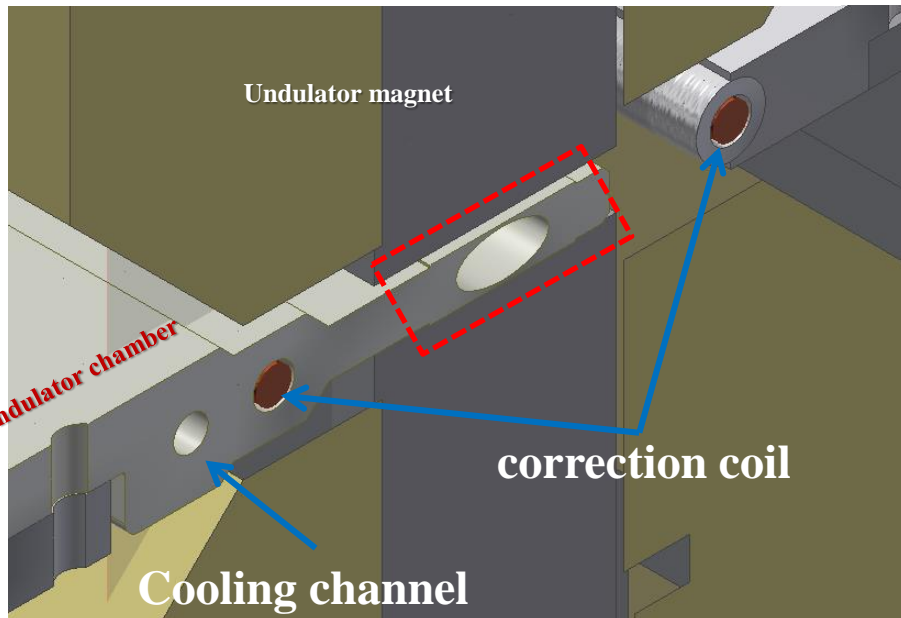
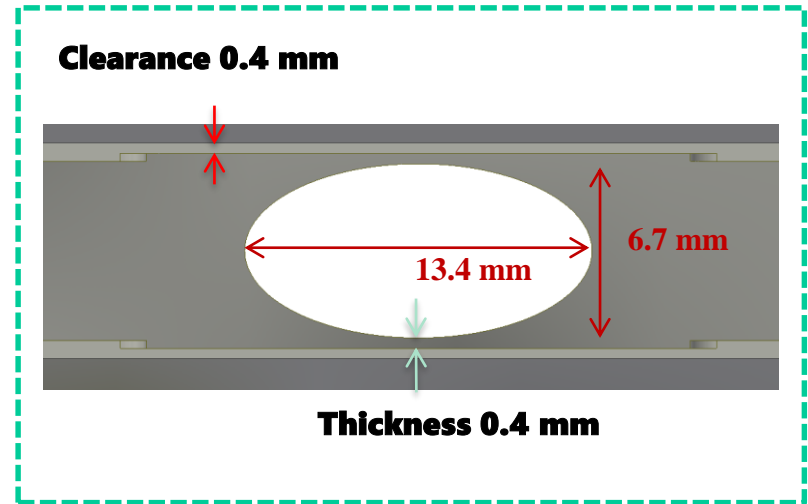
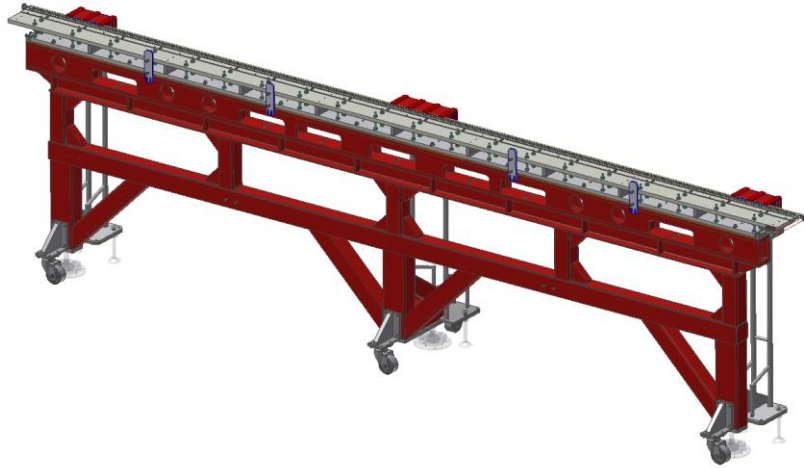


Symbol	Unit	Nominal value
E	GeV	10.000
g	mm	8.30
λ_u	mm	26.0
L_{und}	m	5.0
λ_r	nm	0.1
B_{eff}	Tesla	0.8124
K		1.9727
Optical phase error	degree	less than 5.0

Undulator Intersection



Undulator Vacuum Chamber



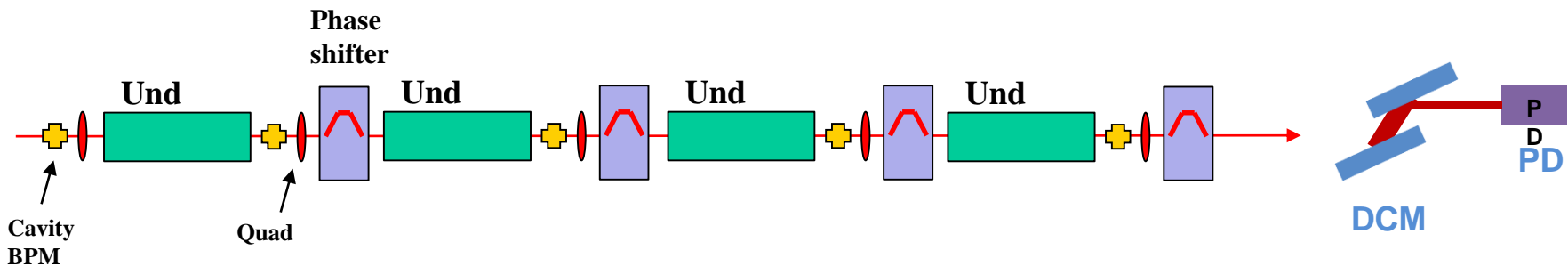
- Surface roughness : **< 150 nm**
 - Chemical polishing
- Oxide layer thickness : **< 7 nm**
 - Chemical Cleaning

Commissioning Status

- ◆ Nov 2015 RF conditioning Started
- ◆ 14 April 2016 Beam commissioning Started
- ◆ 25 April 10 GeV acceleration Achieved
- ◆ 03 June Dipole edge radiation Observed
- ◆ 12 June Undulator radiation Observed
- ◆ 14 June First SASE lasing at 0.5 nm
- ◆ July Summer maintenance for 1 month
- ◆ 30 August SASE lasing at 0.5 nm (재현)
- ◆ 09 September Beamline commissioning with 0.5 nm FEL is Completed
- ◆ 08 October Lasing at 0.35 nm
- ◆ 16 October Lasing at 0.2 nm
- ◆ ? Lasing at 0.15 nm

- ◆ To establish a straight orbit along the undulators
- ◆ All correctors of undulator line are turned OFF and **Undulator gap are fully open (200 mm)**
- ◆ BPM offsets and quad offsets are calculated to get dispersion-free straight orbit
- ◆ All cavity BPMs and quads have its own mover which can move up to +/-1 mm with precision of 1 μ m for horizontal and vertical directions.
- ◆ Cavity BPM's resolution is essential for BBA performance

- Beam positions are measured at four different beam energy: **4, 5.2, 6.7, 10 GeV**
- At least 7 or 8 steps is required. It takes about 2 to 3 hours

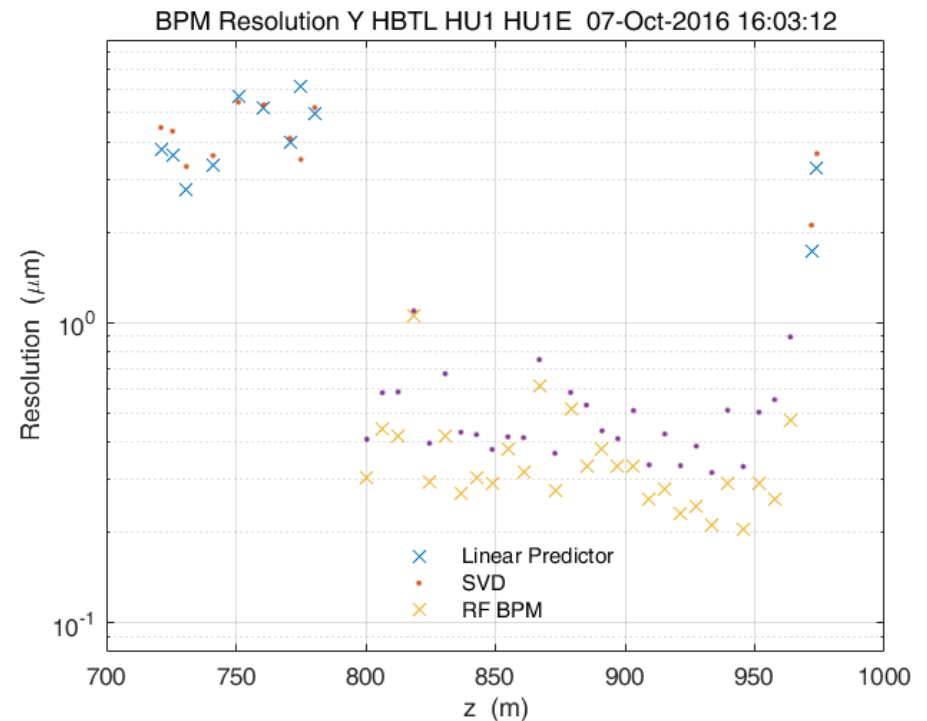
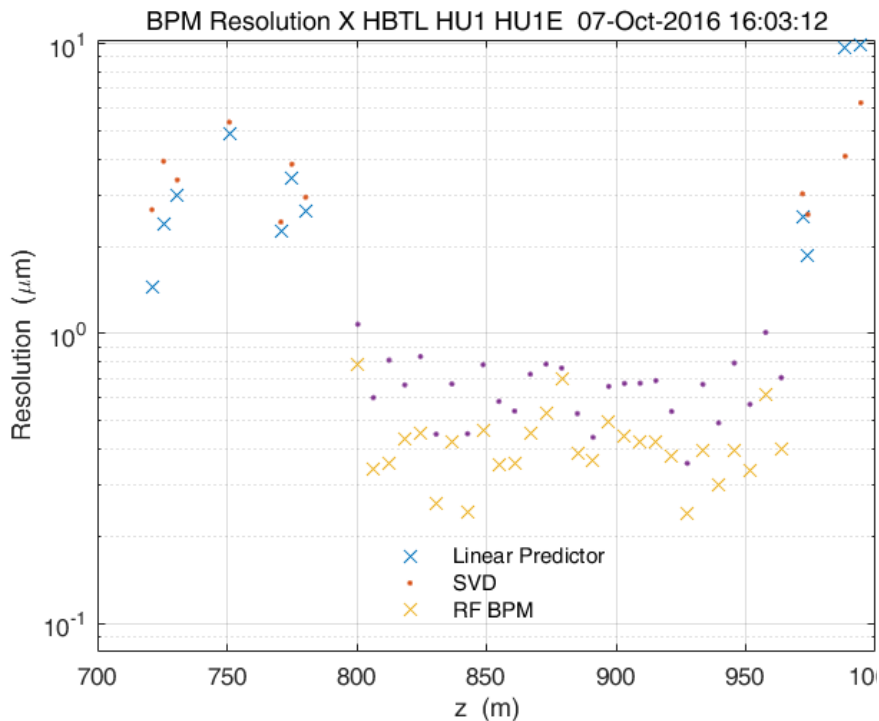


Cavity BPM resolution



horizontal

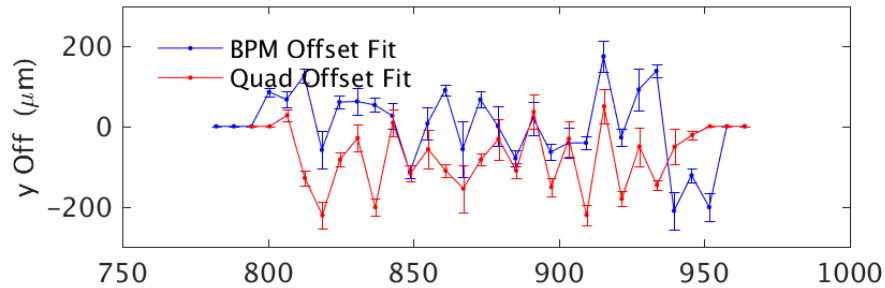
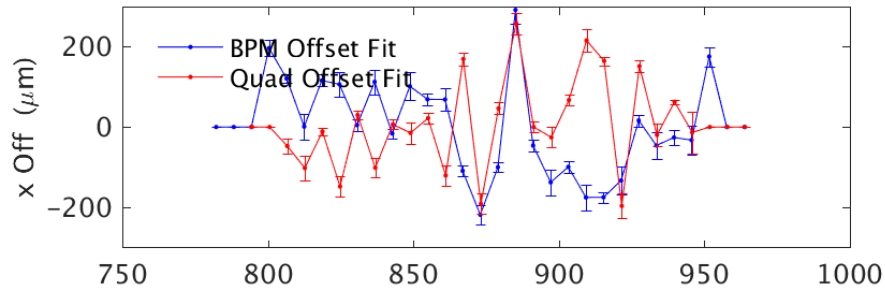
vertical



Beam Based Alignment for Undulators

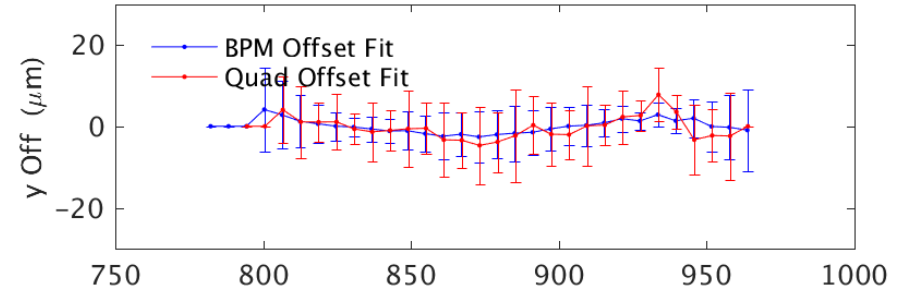
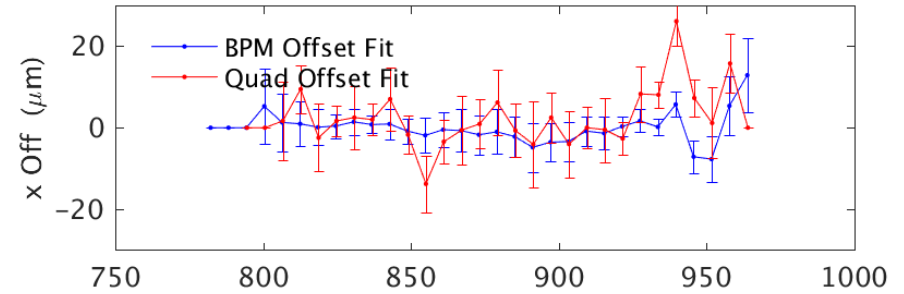
1-st step

BBA Scan Fit Result 07-Oct-2016 10:04:27

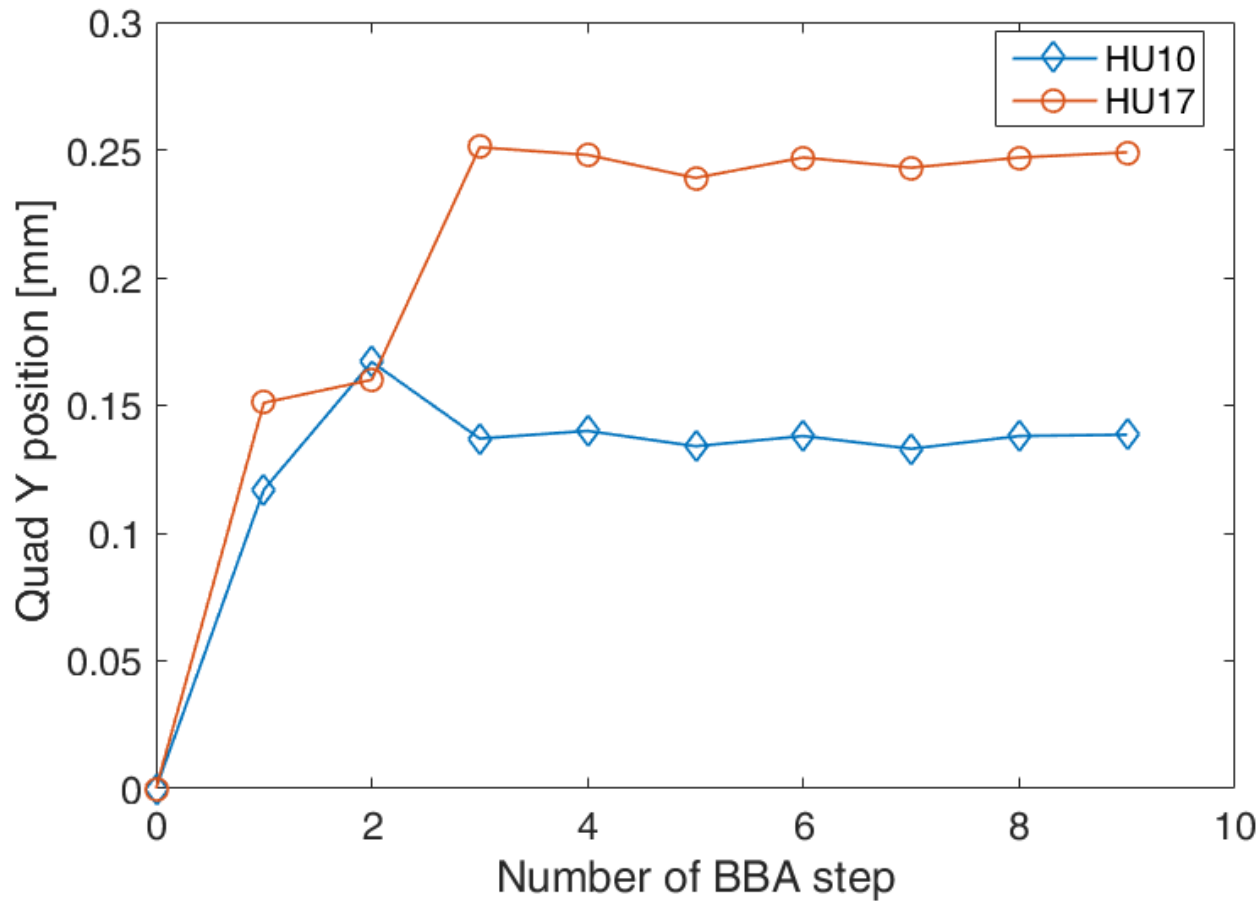


8-th step

BBA Scan Fit Result 07-Oct-2016 12:41:51

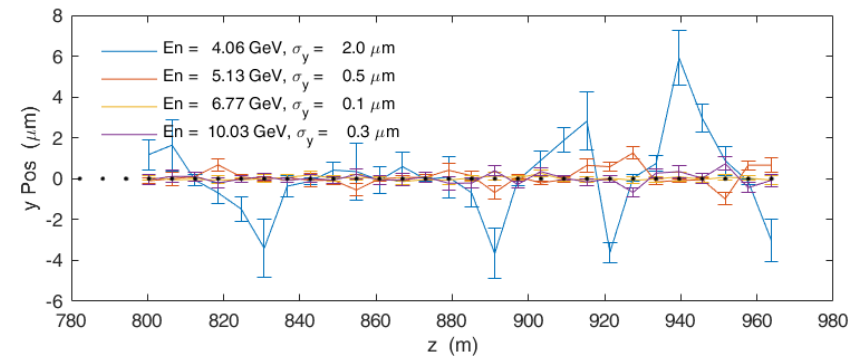
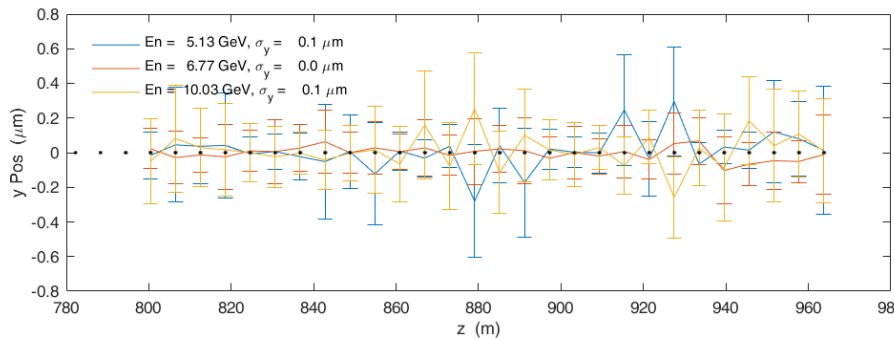
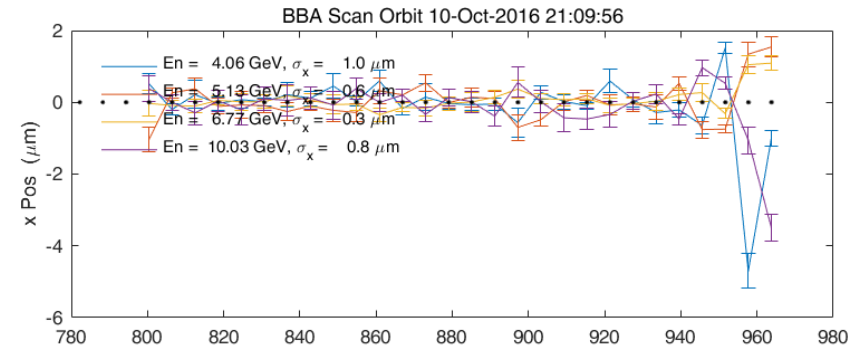
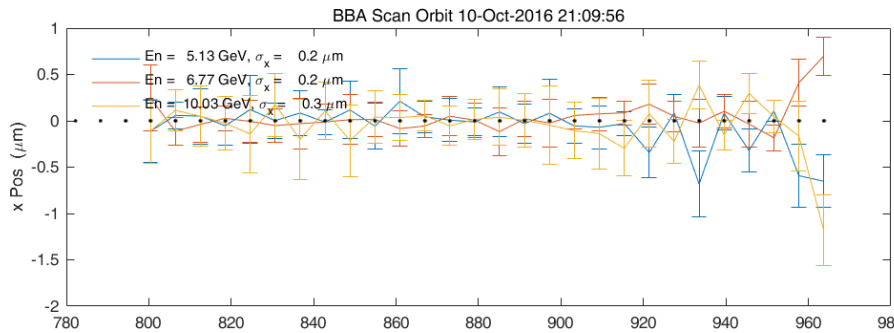


Quad Position vs. Number of BBA step



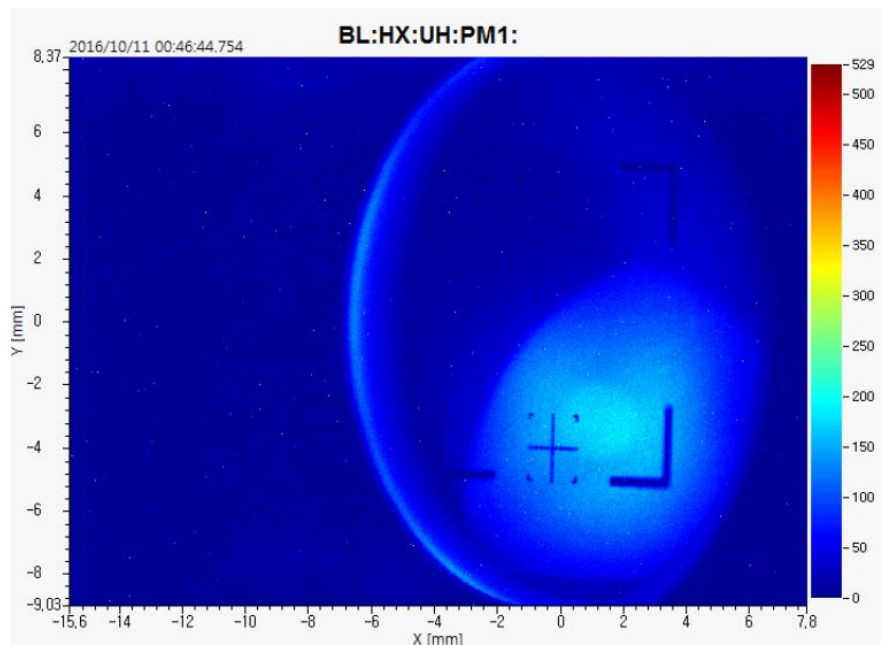
3 Energy: 5.2, 6.7, 10 GeV

4 Energy: 4, 5.2, 6.7, 10 GeV

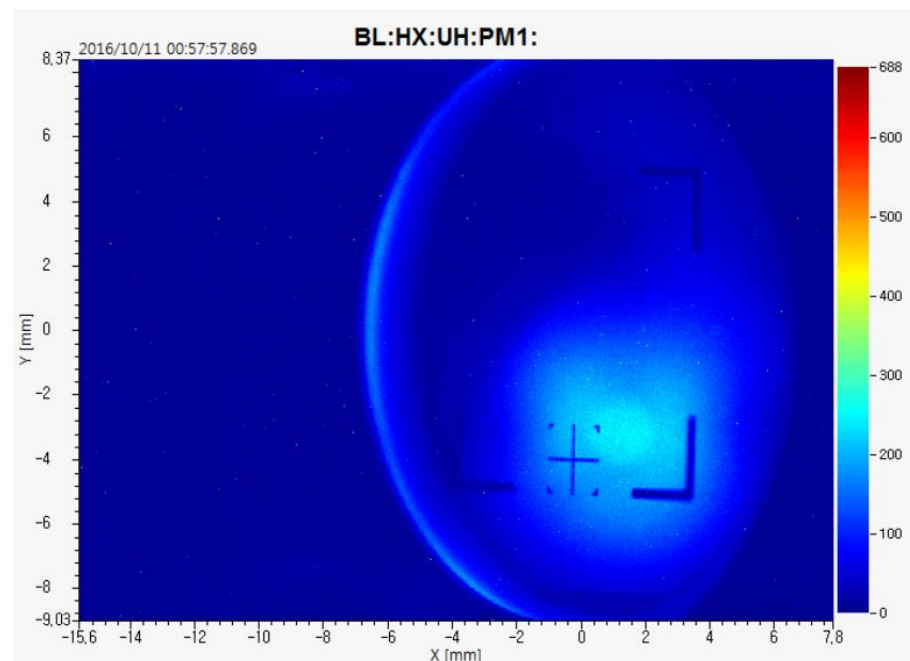


Undulator Radiation

HU122

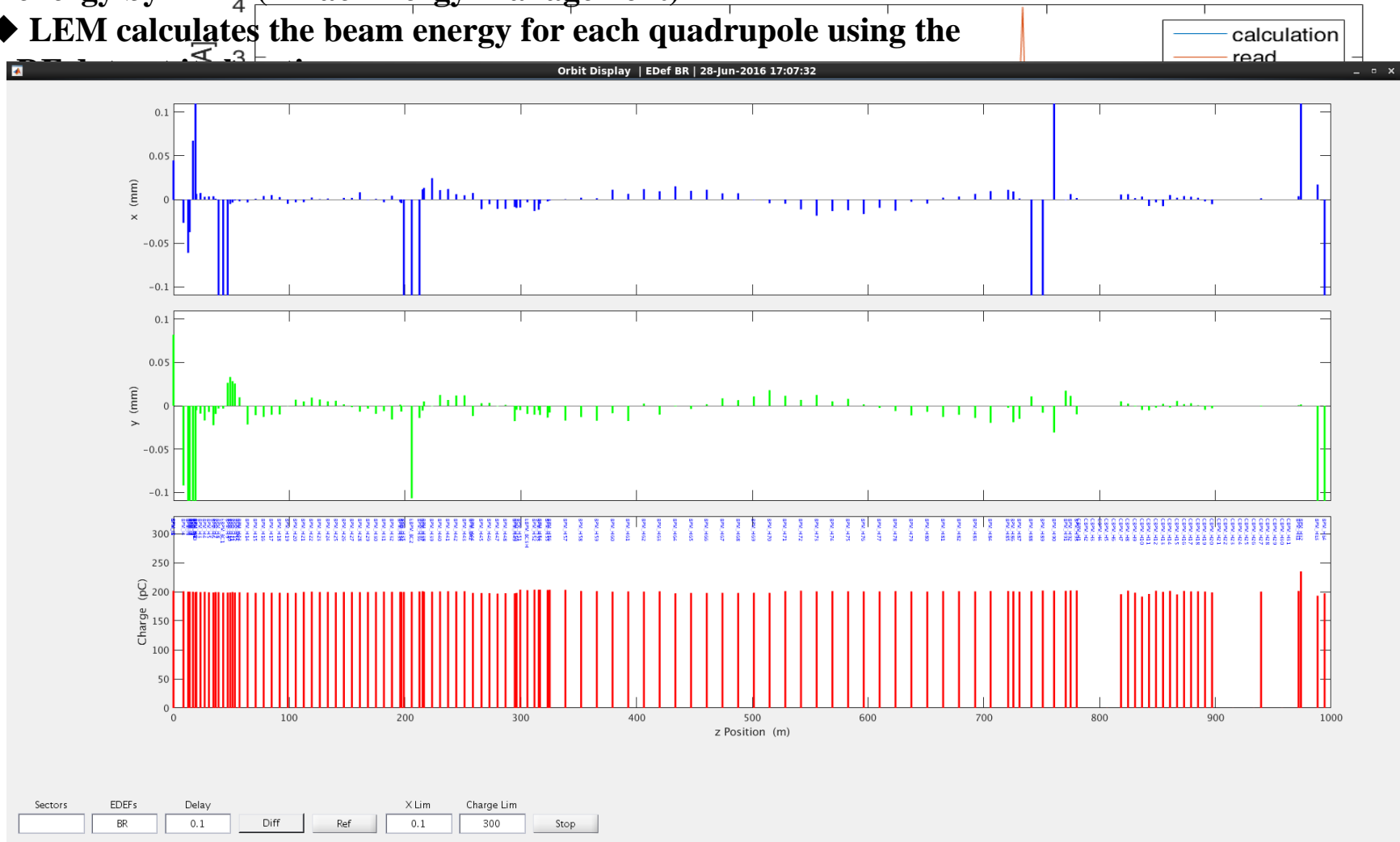


HU124

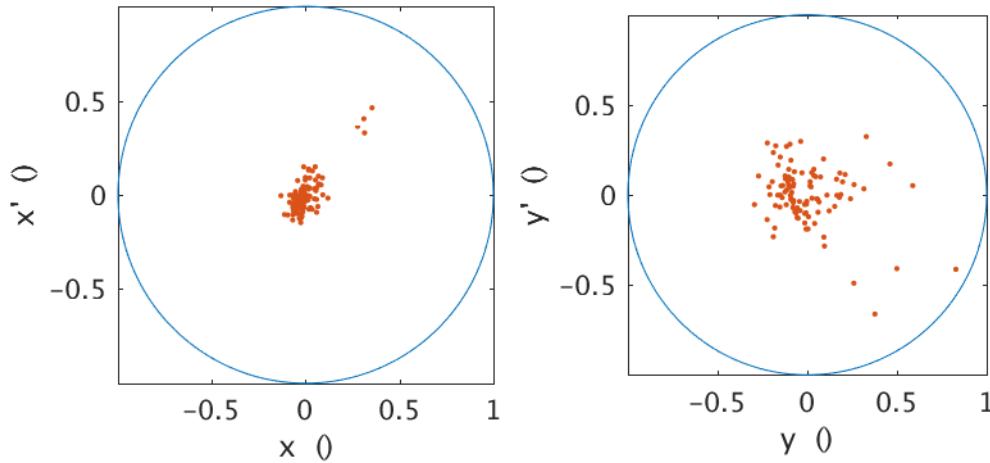


Global Orbit Feedback

- ◆ Global orbit feedback runs from Injector end to Main dump
- ◆ It uses the design lattice function and the calculated beam energy by LEM (Linac Energy Management)
- ◆ LEM calculates the beam energy for each quadrupole using the

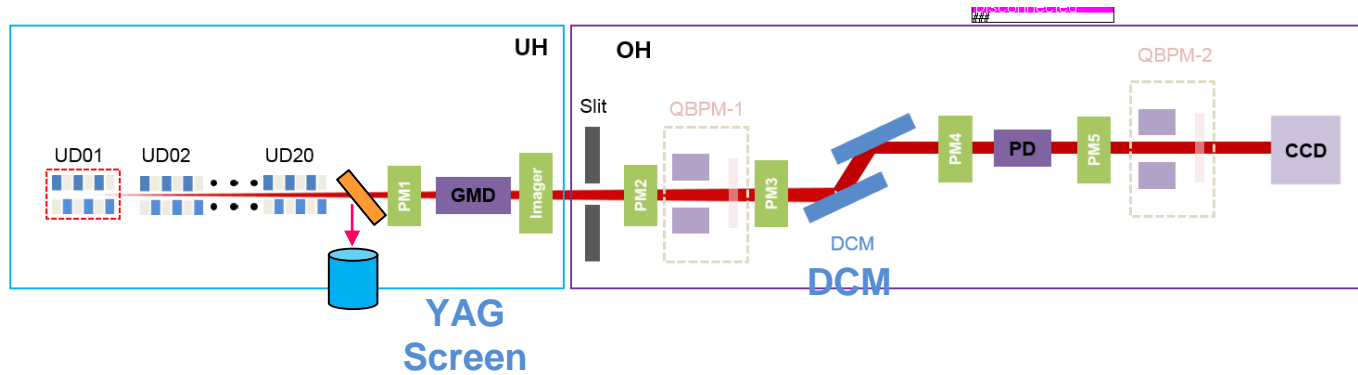


Electron Beam Stability

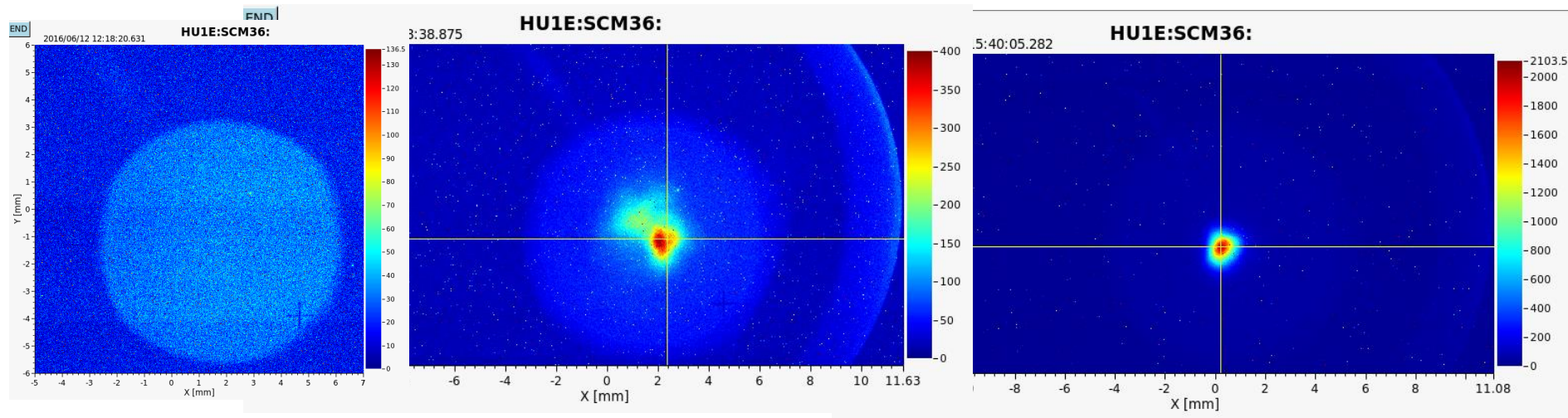


- ✓ Circle represents a phase space of 1 μm emittance electron beam
- ✓ Electron beam jitters in position and angle are much smaller than the phase space

First Lasing at 0.5 nm on 14 June



Spontaneous radiation



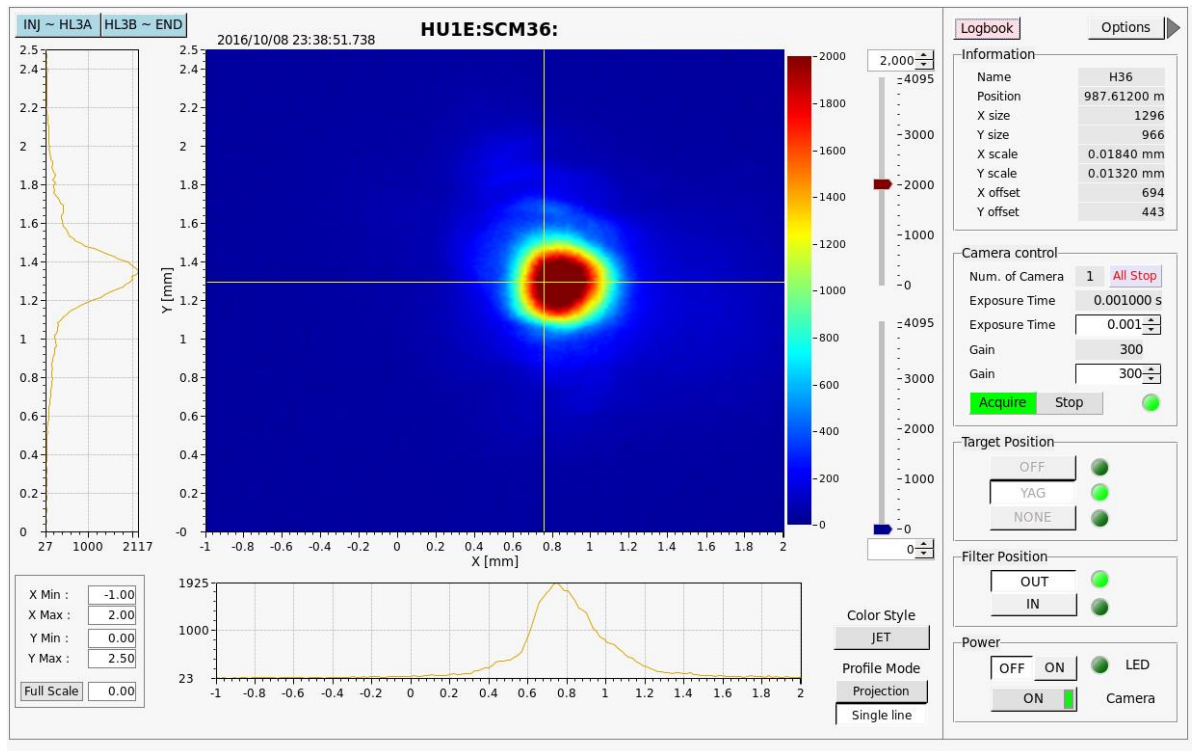
12 June 2016

05:01, 14 June 2016

16 June 2016

0.35 nm FEL (08 Oct. 2016, 2:13 pm)

- Beam energy: 5.2 GeV
- Undulator gap: 9 mm
- Undulator K: 1.87
- Number of undulators: 20
- Undulator BBA is applied

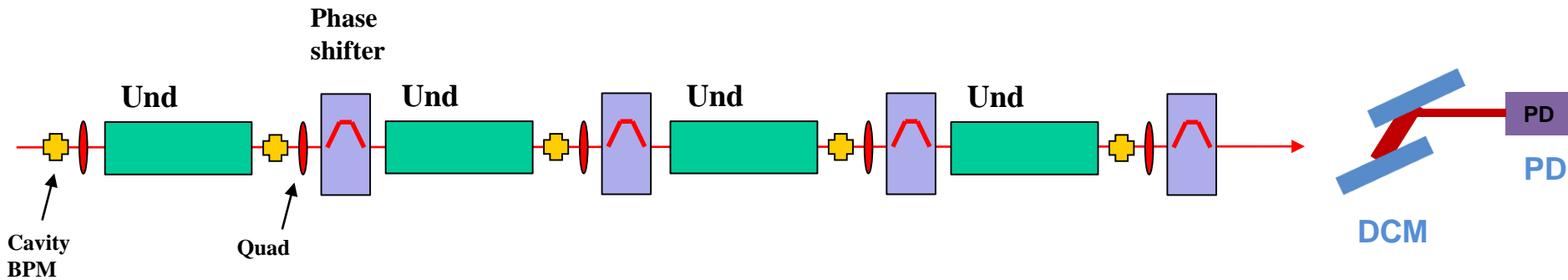


Undulator Optimization

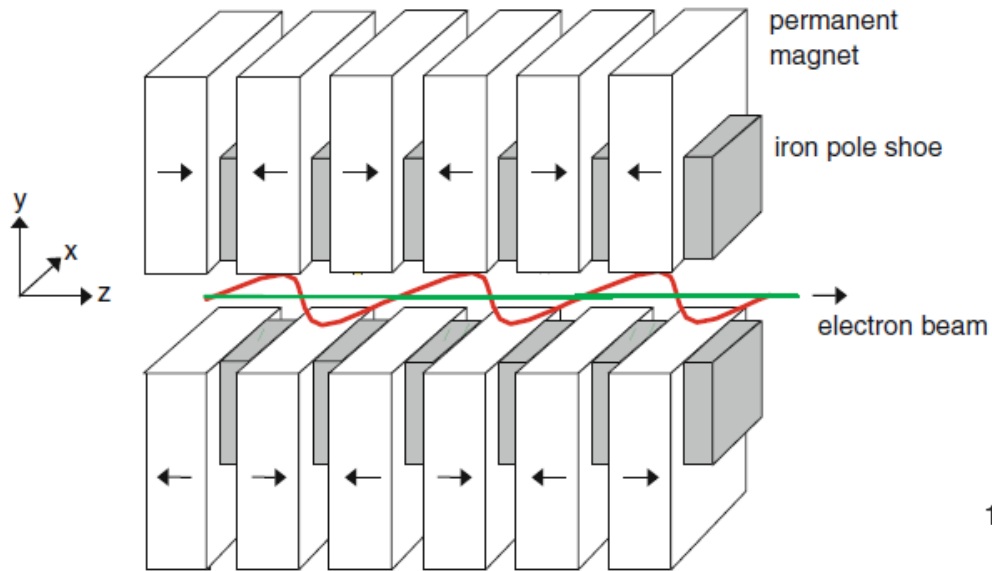
- ✓ Lasing of 0.15 nm FEL is not so easy to achieve as 0.5 nm FEL.
- ✓ Requirements for lasing are very stringent.
- ✓ Procedures for Undulator optimization are established

- K-value tuning
- Undulator Field Center
- Phase matching
- Undulator Tapering (TBD)

$$\lambda_r = \frac{\lambda_w}{2\gamma^2} \left(1 + \frac{k^2}{2}\right)$$



Undulator Field



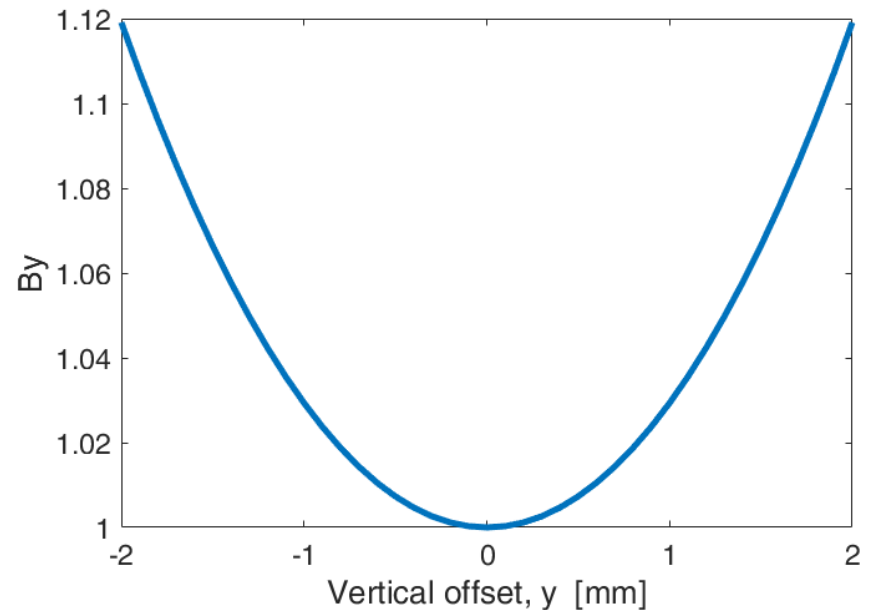
$$B_x = 0,$$

$$B_y = -B_0 \cosh(k_u y) \sin(k_u z),$$

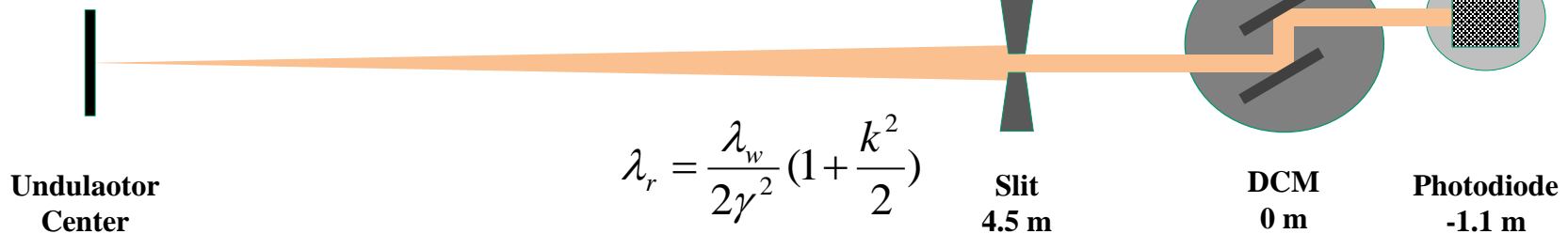
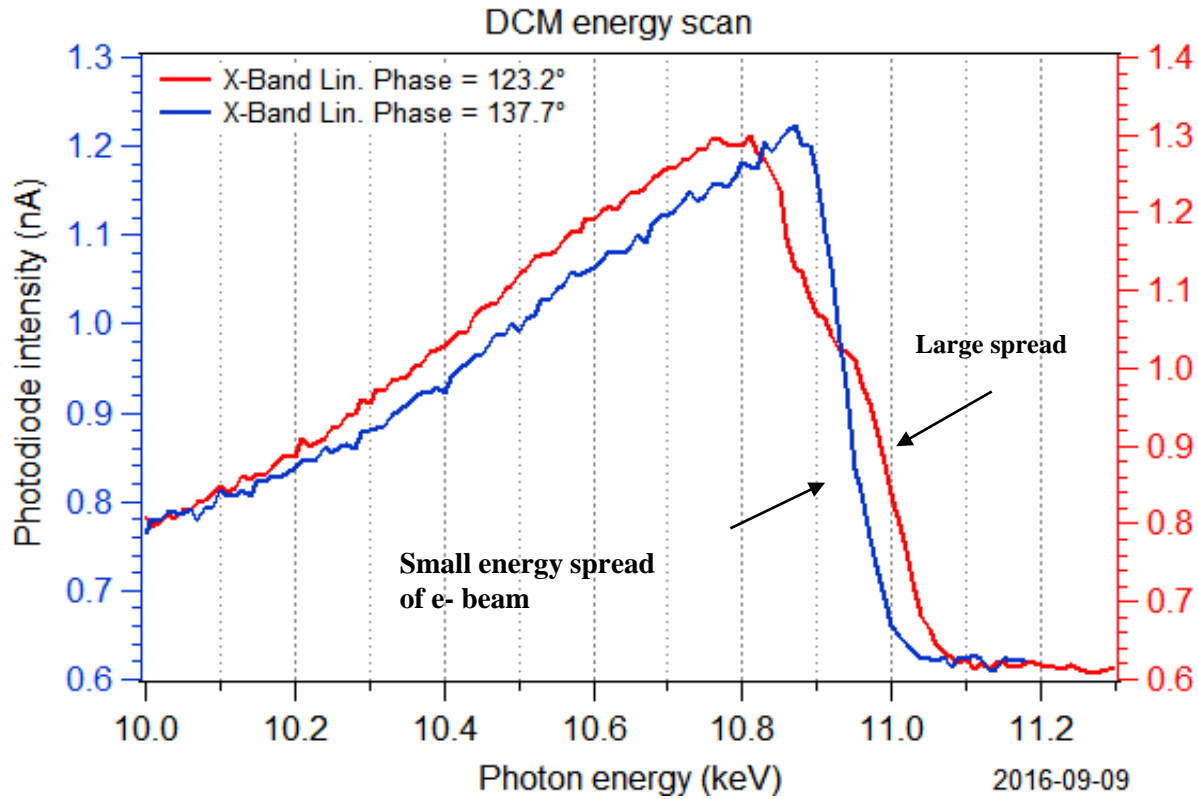
$$B_z = -B_0 \sinh(k_u y) \cos(k_u z).$$

$$\lambda_r = \frac{\lambda_w}{2\gamma^2} \left(1 + \frac{k^2}{2}\right)$$

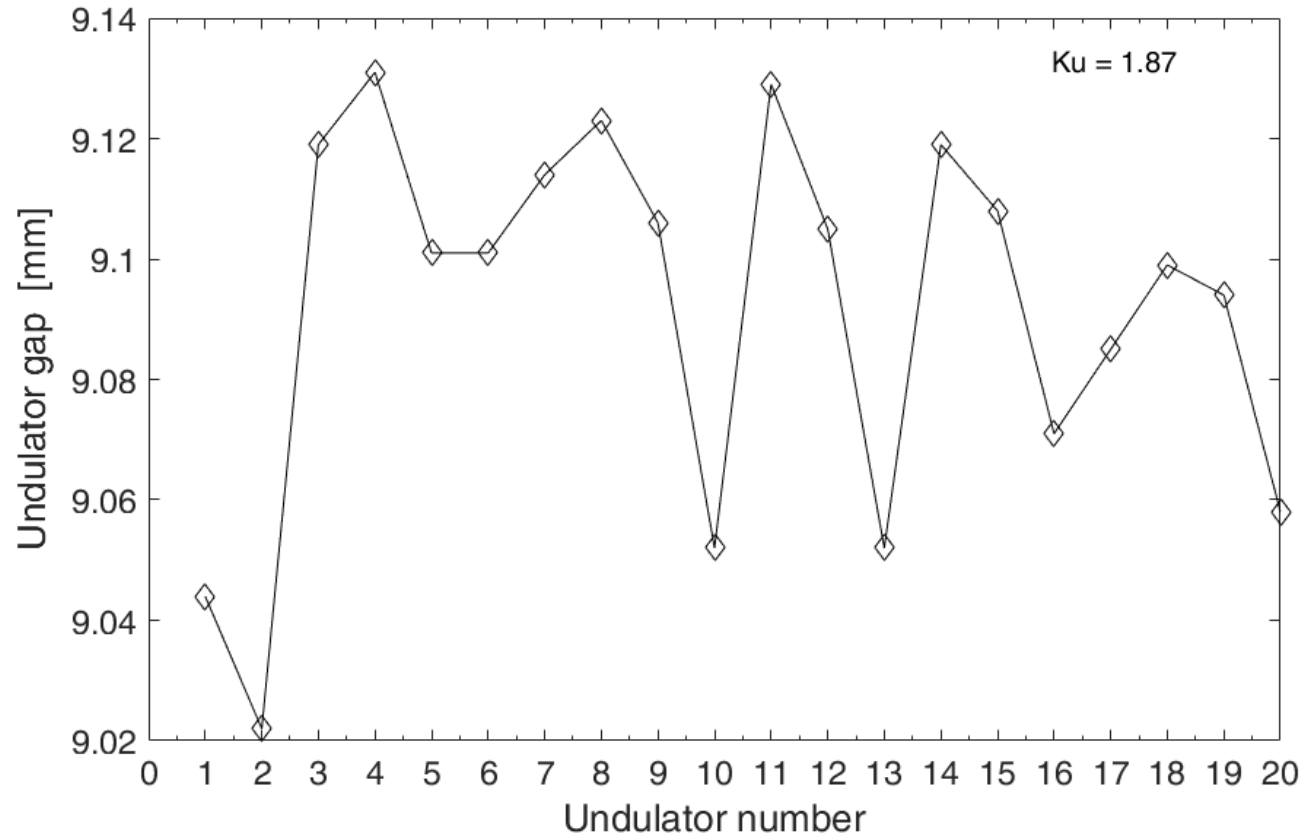
$$K \equiv \frac{e B_0 \lambda_u}{2\pi m c} = 0.9337 B_0(\text{T}) \lambda_u(\text{cm})$$



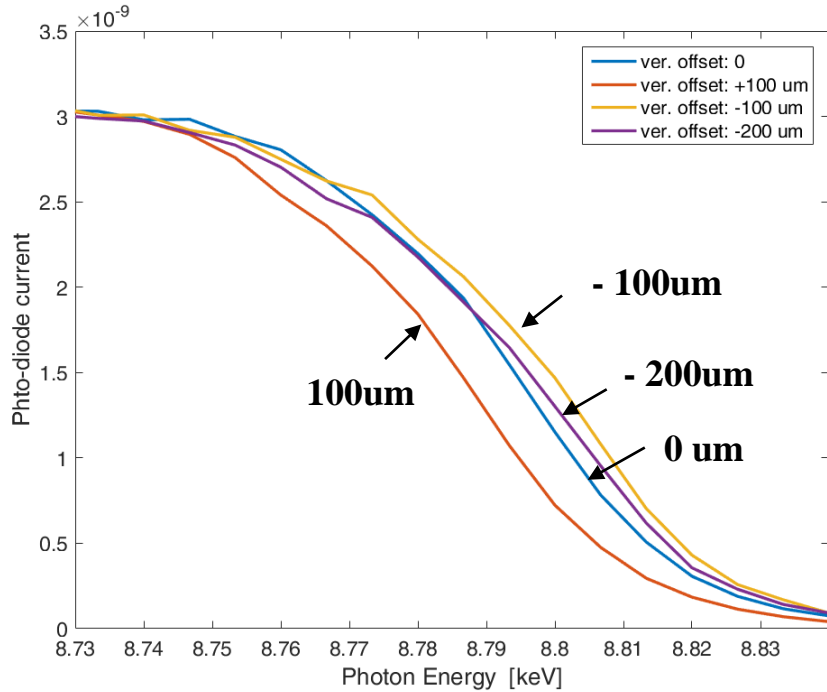
Undulator K-tuning



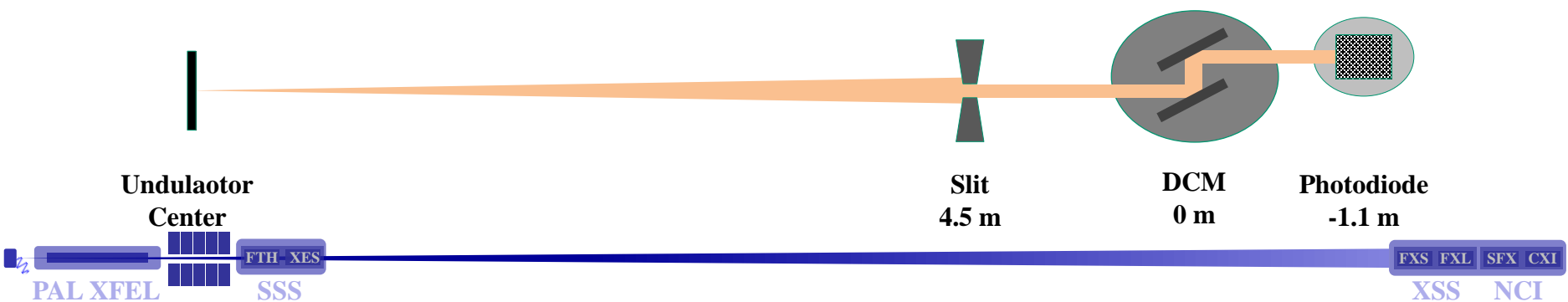
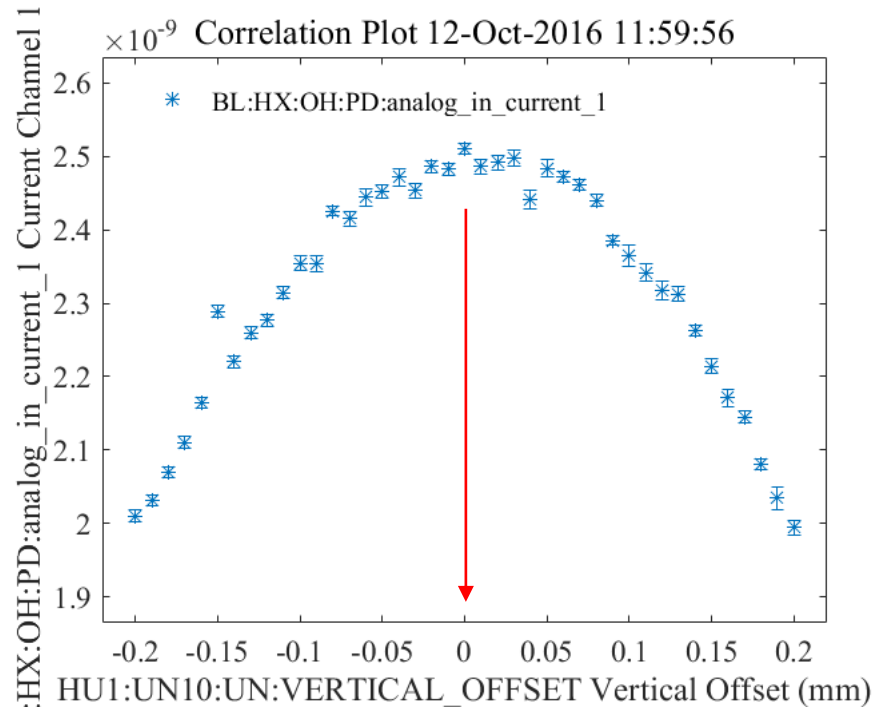
K-tuning Gap



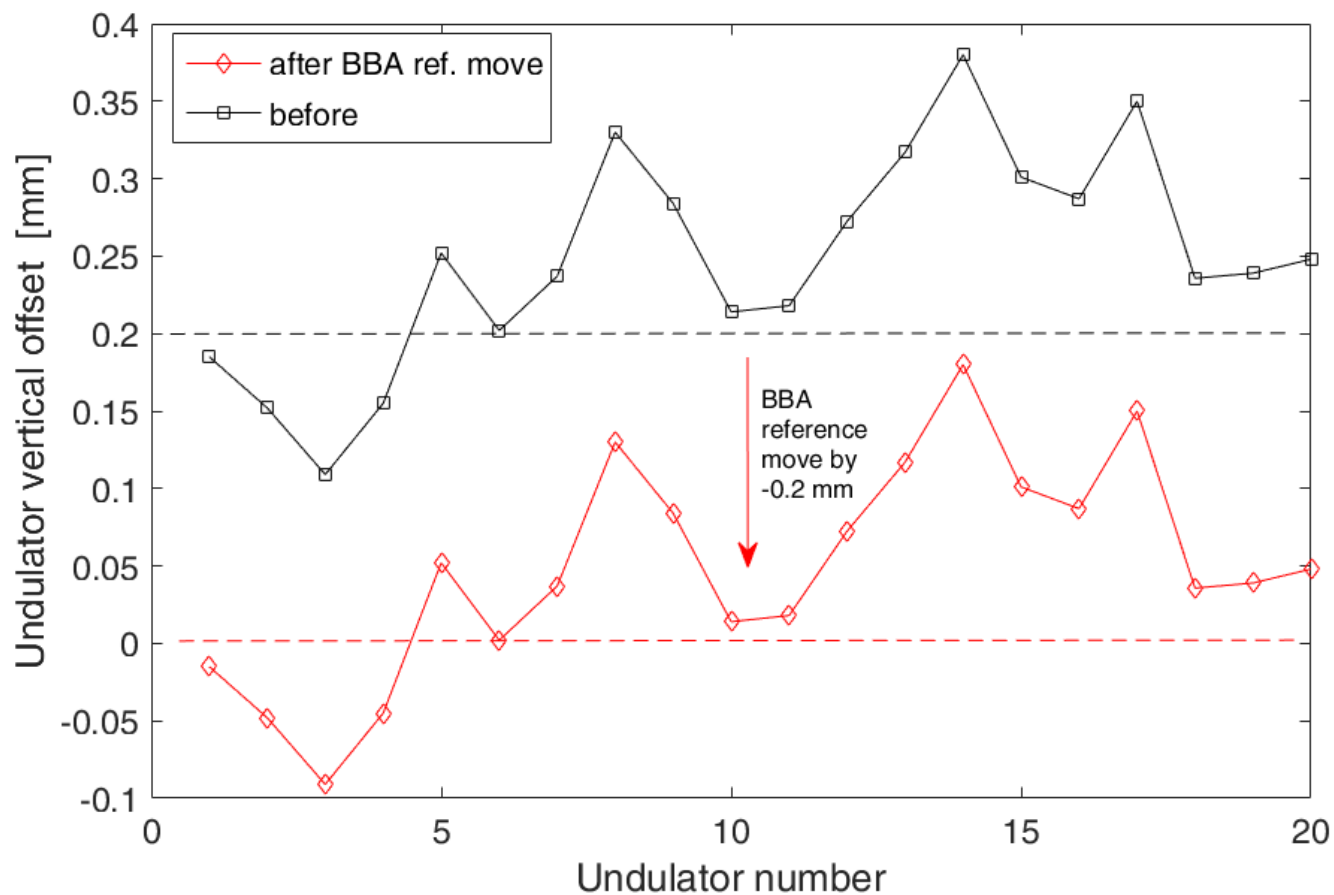
Undulator Radiation Spectrum for Different Vertical offset



Undulator Field Center Position

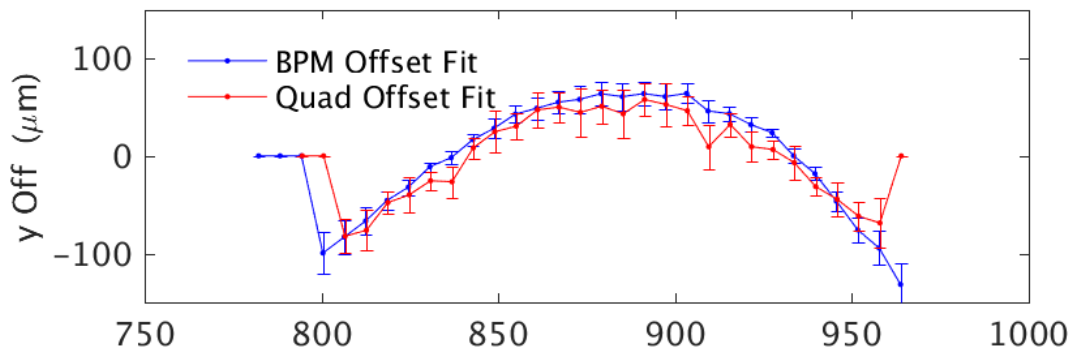
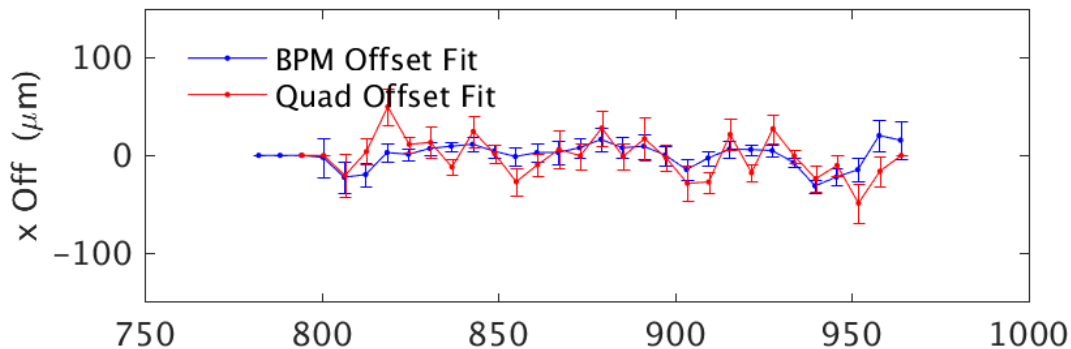


Undulator Vertical Offset



BBA with Undulator gap closed

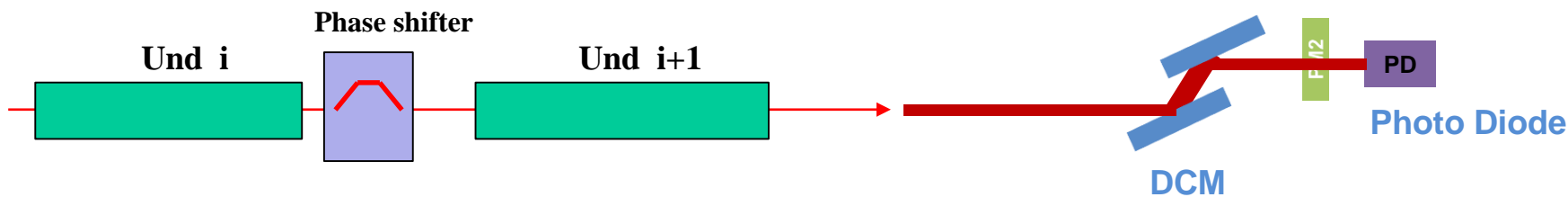
BBA Scan Fit Result 07-Oct-2016 18:28:58



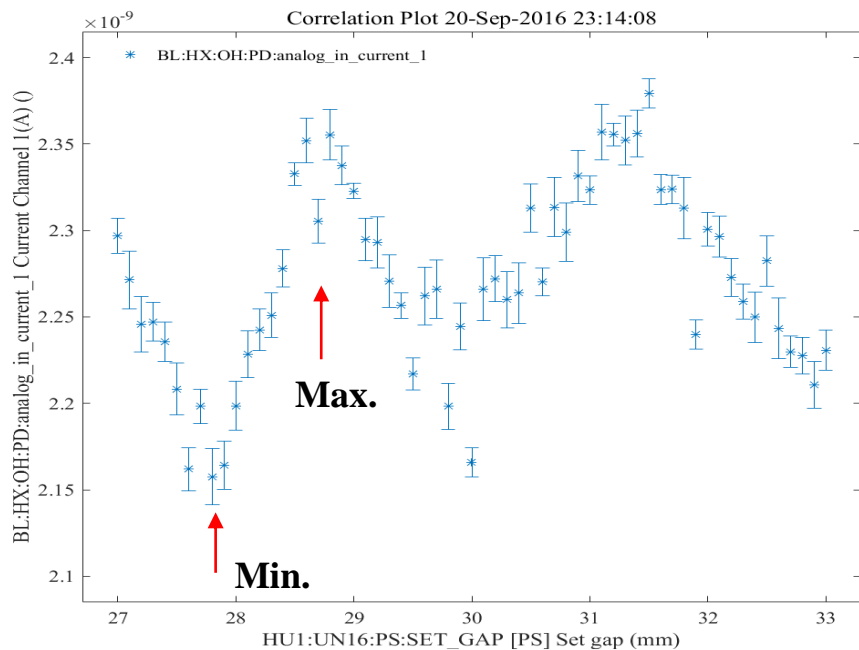
- ✓ BBA was done with undulator gap closed to 9 mm
- ✓ In vertical plane, **a bow pattern** of BPM offsets and quad offsets is clearly shown
- ✓ It is because the undulator natural focusing strength increases as the vertical offset of undulator increases.
- ✓ It is not corrected in the BBA
- ✓ Decide to use OPEN GAP

$$\frac{d^2 y_{\beta n}}{dz^2} \approx -\left(\frac{K_0^2 k_u^2}{2\gamma_0^2}\right) y_{\beta n} \equiv -k_{n0}^2 y_{\beta n}$$

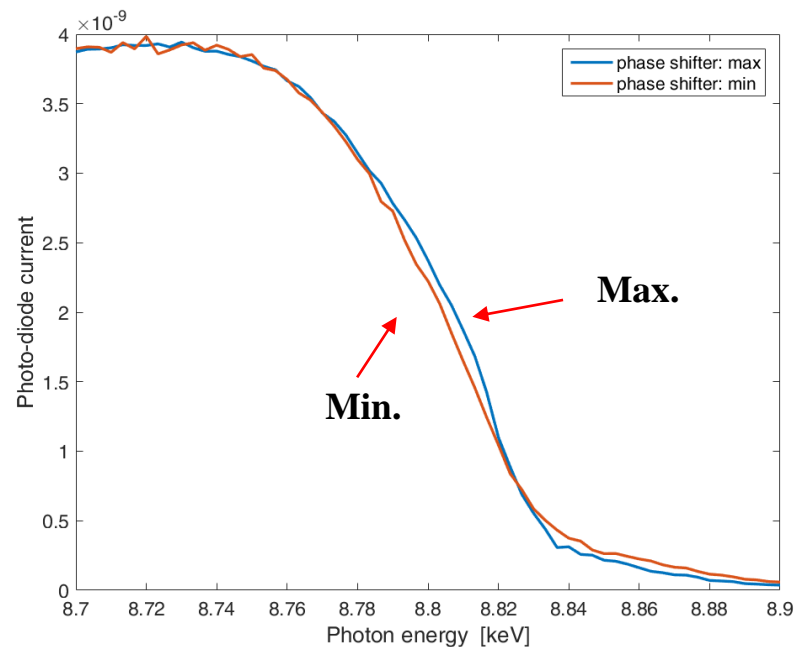
Phase Matching by Phase-shifter



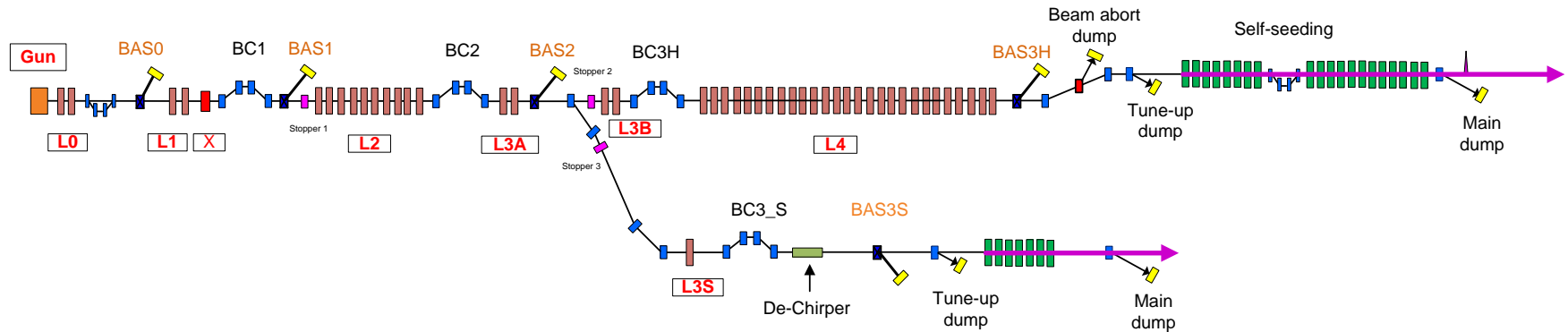
Phase scan of Phase-shifter



Radiation Spectrum from two undulators



Electron Beam Manipulation

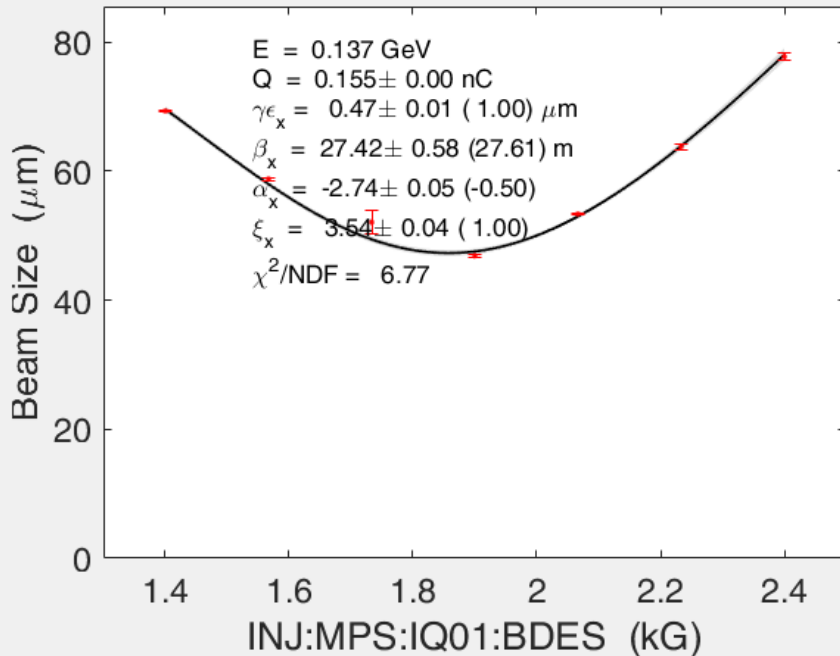


- R56
 - BC1: 66.7 mm
 - BC2: 45 mm
 - BC3: 0 mm
- Bunch length
 - Injector: 877.5 μm
 - BC1: 92 μm (CR = 9.5)
 - BC2: 3.8 μm (CR = 24.0)
- Beam charge
 - Injector: 150 pC
 - BC1: 120 pC
 - BC2: 120 pC or 80 pC (by using a collimator at BC2)
 - Undulator: 80 pC
- Emittance (Projected)
 - Injector: 0.48 / 0.42 mm-mrad
 - Linac End: 1.23 / 2.69 mm-mrad
- RF phase

• Gun :	-37.5
• L1:	-19.5
• X-linearizer:	-180
• L2:	-17.0
• L3, L4:	0.0

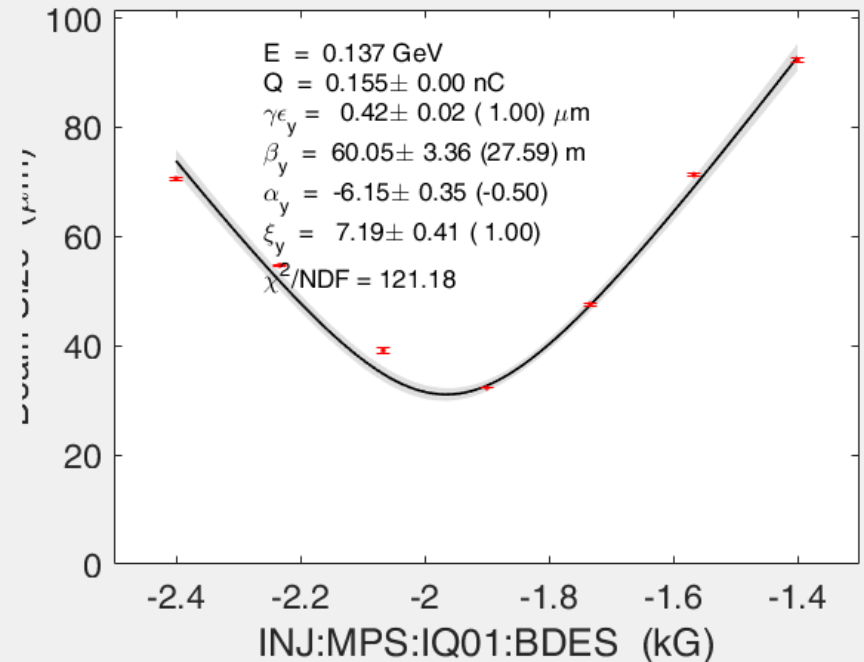
Injector Emittance (Projected)

14-Oct-2016 10:30:47 RMS cut area



Horizontal: **0.47** mm-mrad at 150 pC

14-Oct-2016 10:28:29 RMS cut area

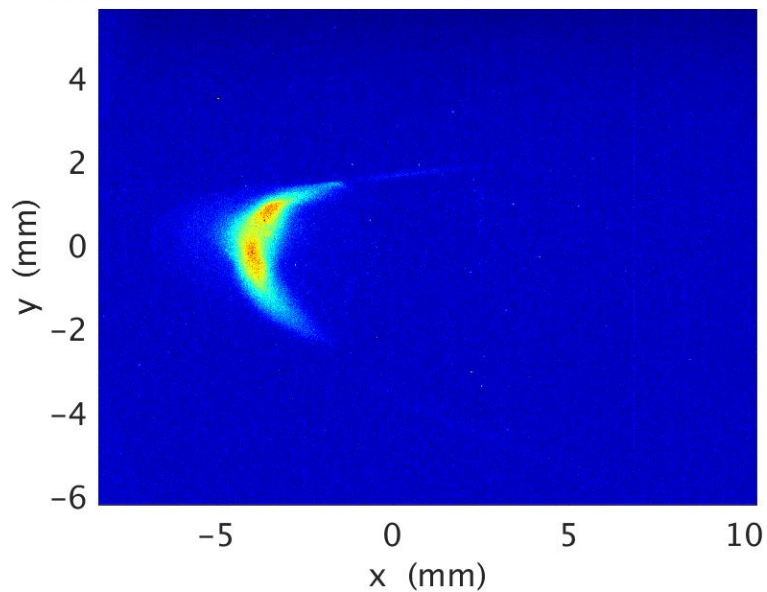


Vertical: **0.42** mm-mrad at 150 pC

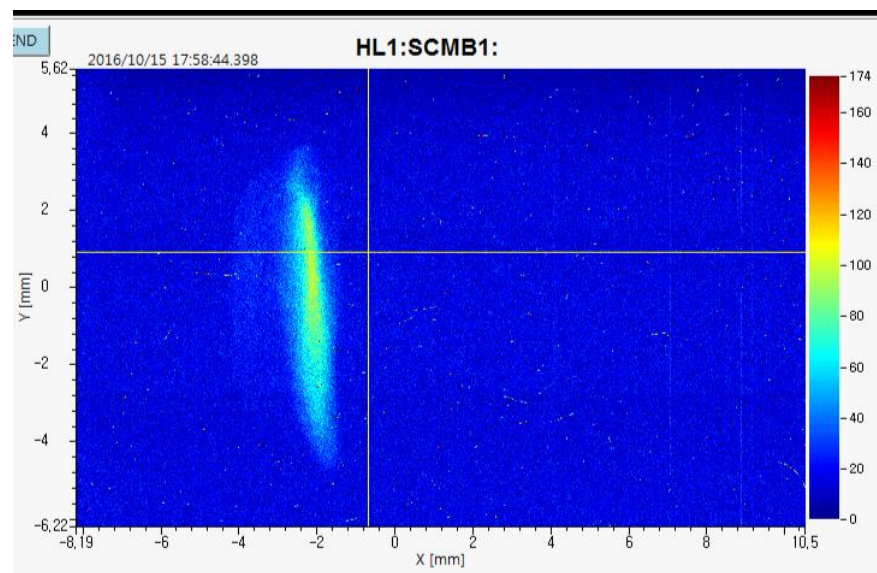
X-linearizer

OFF

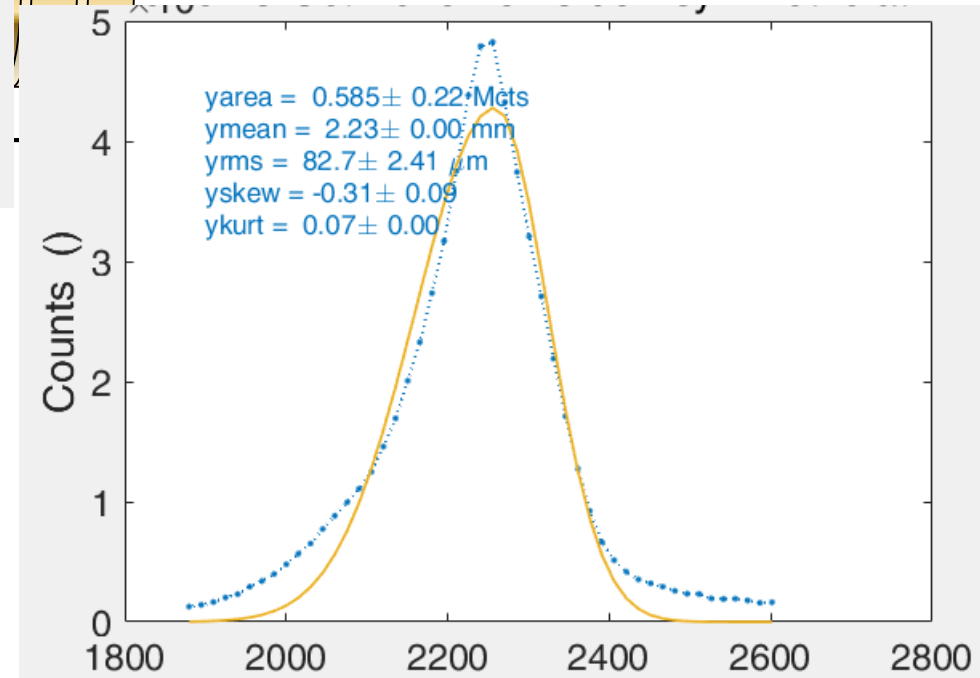
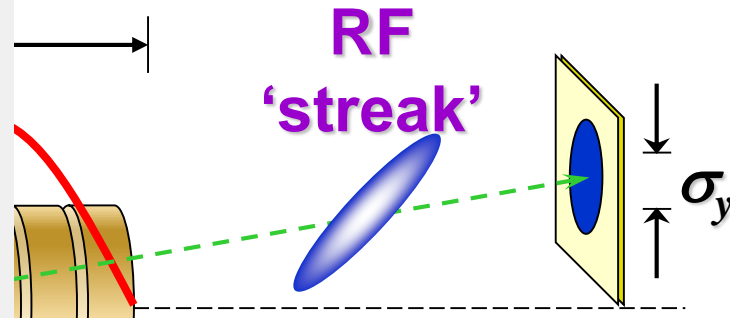
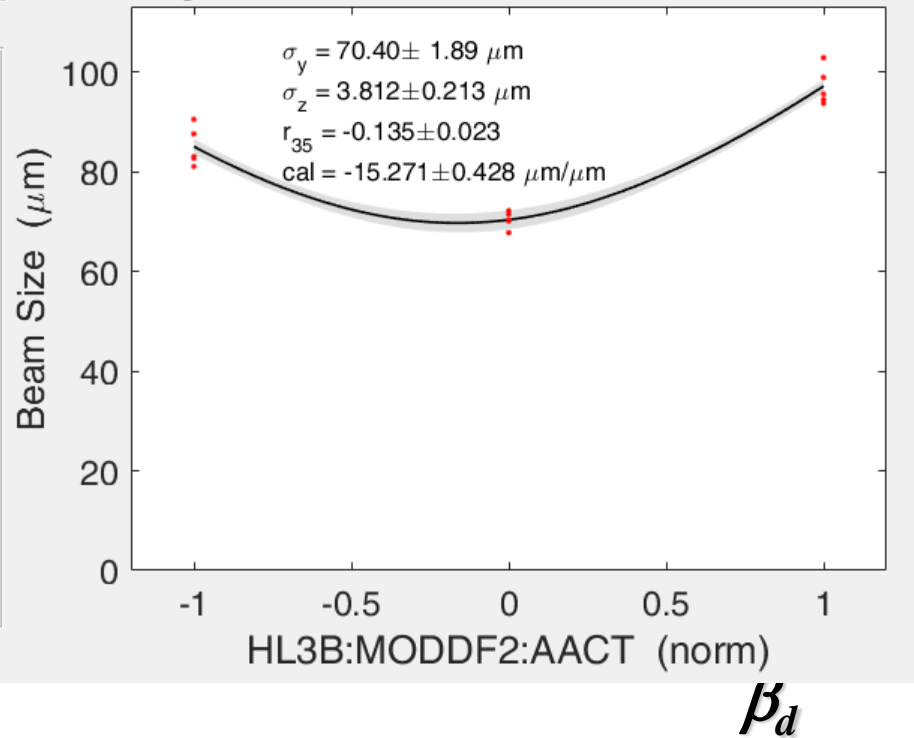
Profile Monitor HL1:SCMB1 15-Oct-2016 16:48:16



ON



Bunch Length Measurement

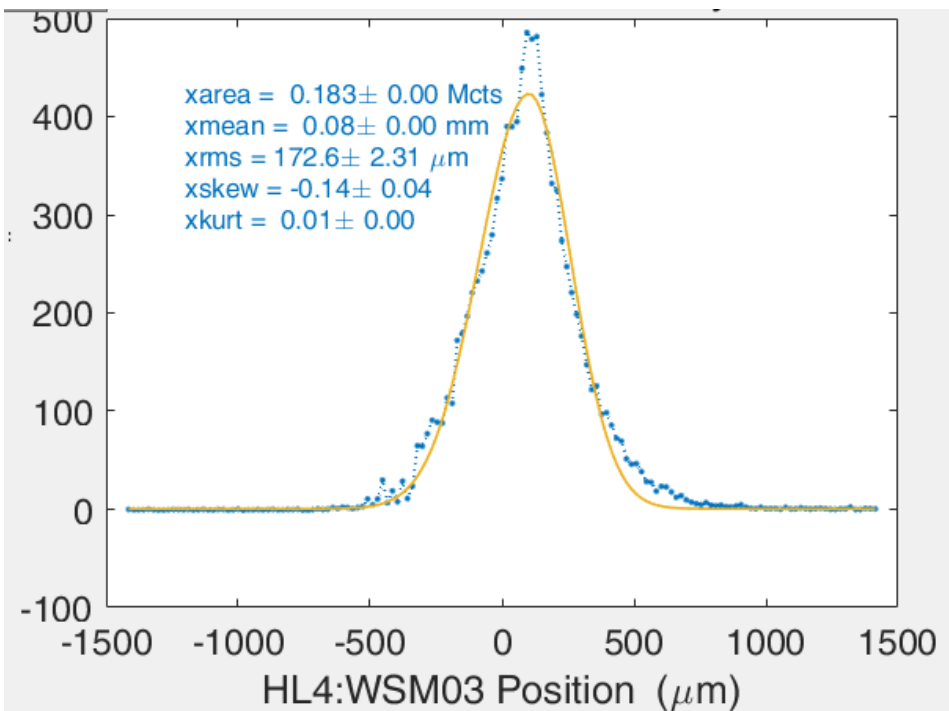


Bunch length: 3.8 μm \rightarrow 12.7 fs

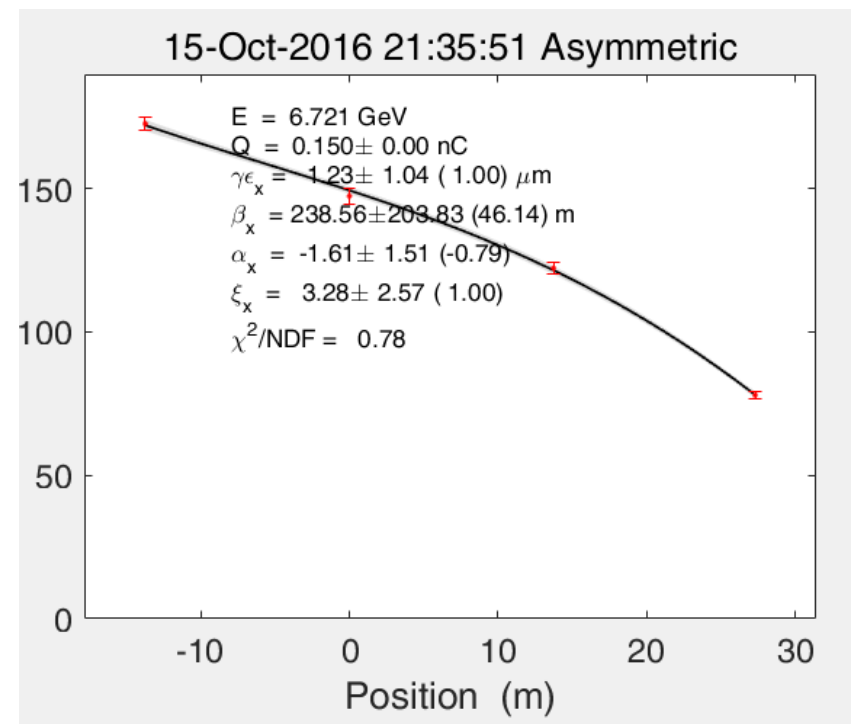
Peak current: 3.7 kA (120 pC)

- Emittance measured with four wire scanners @120 pC
 - Hor. emittance: 1.23 mm-mrad
 - Ver. emittance: 2.69 mm-mrad

Beam size measurement with wire scanner

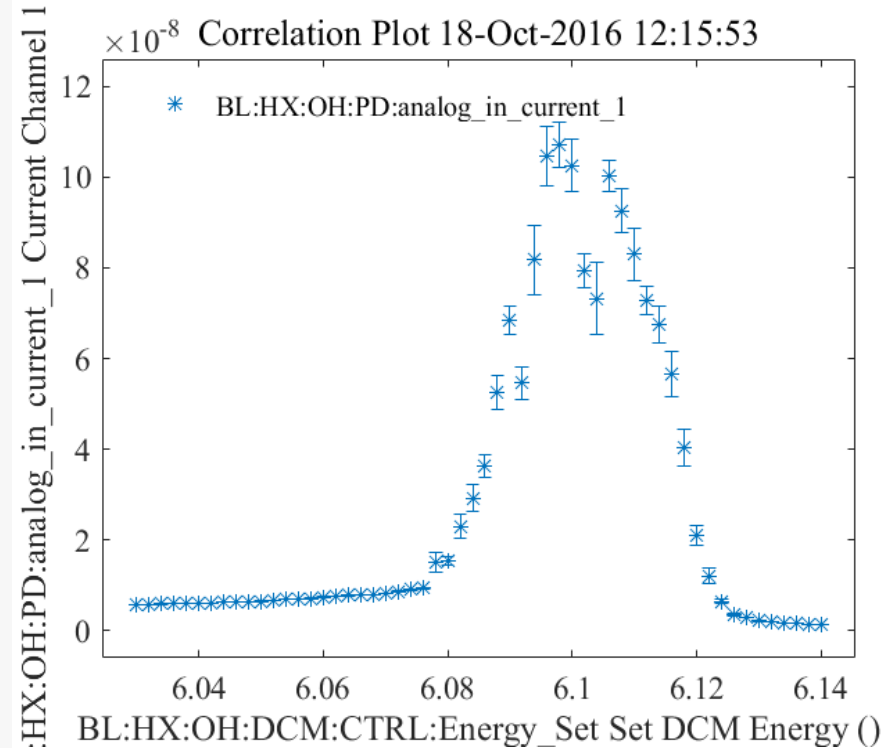
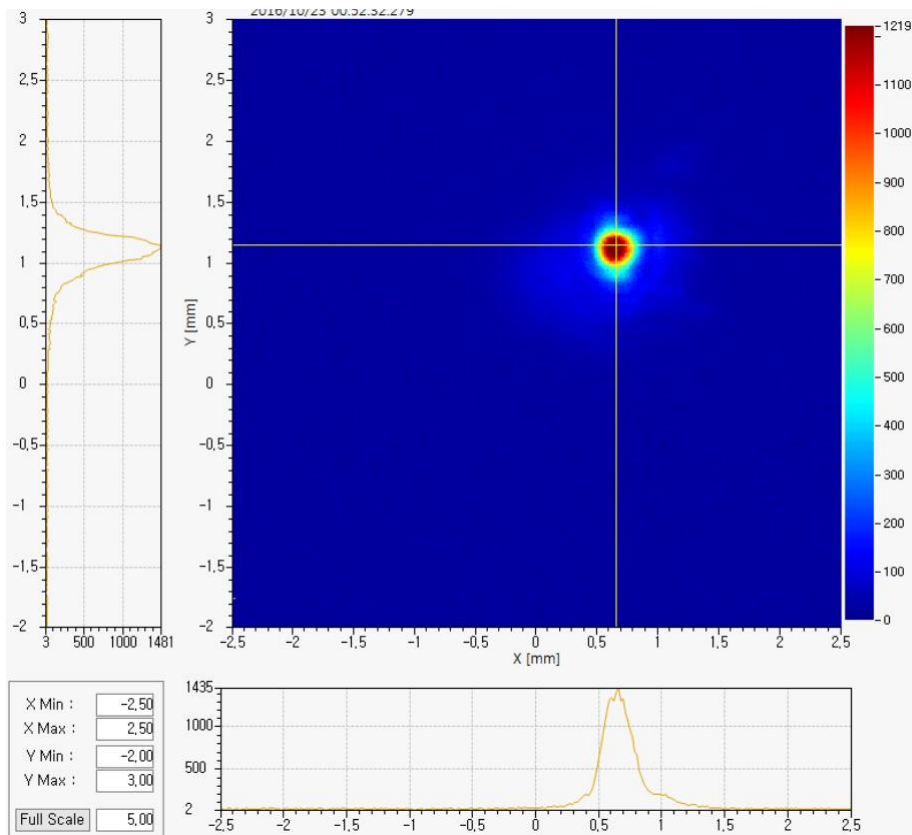


Hor. emittance

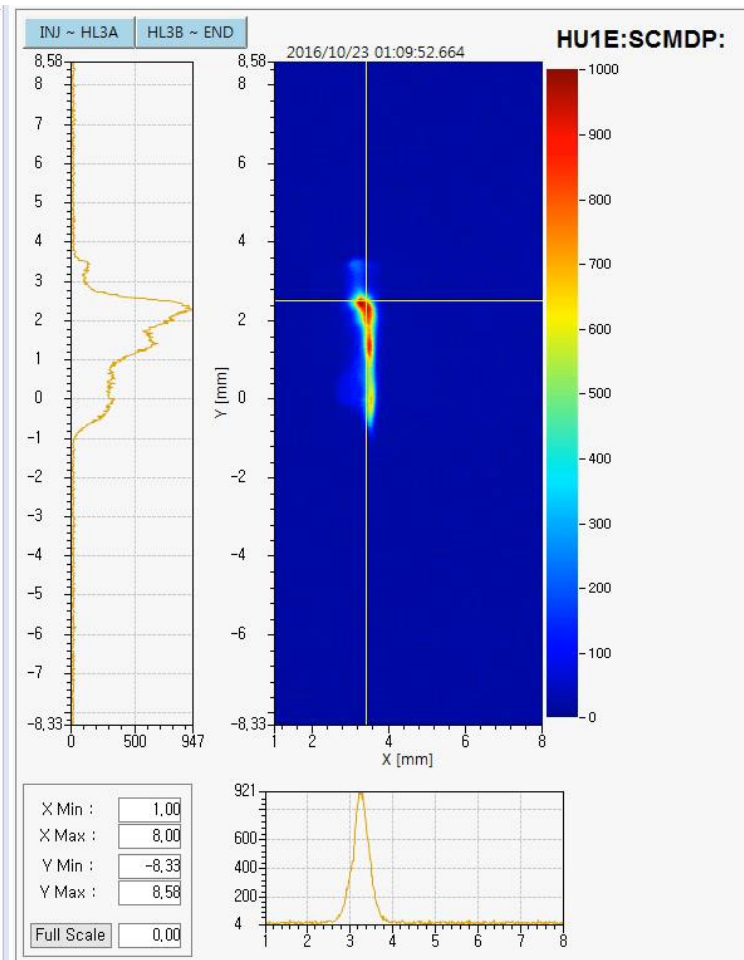
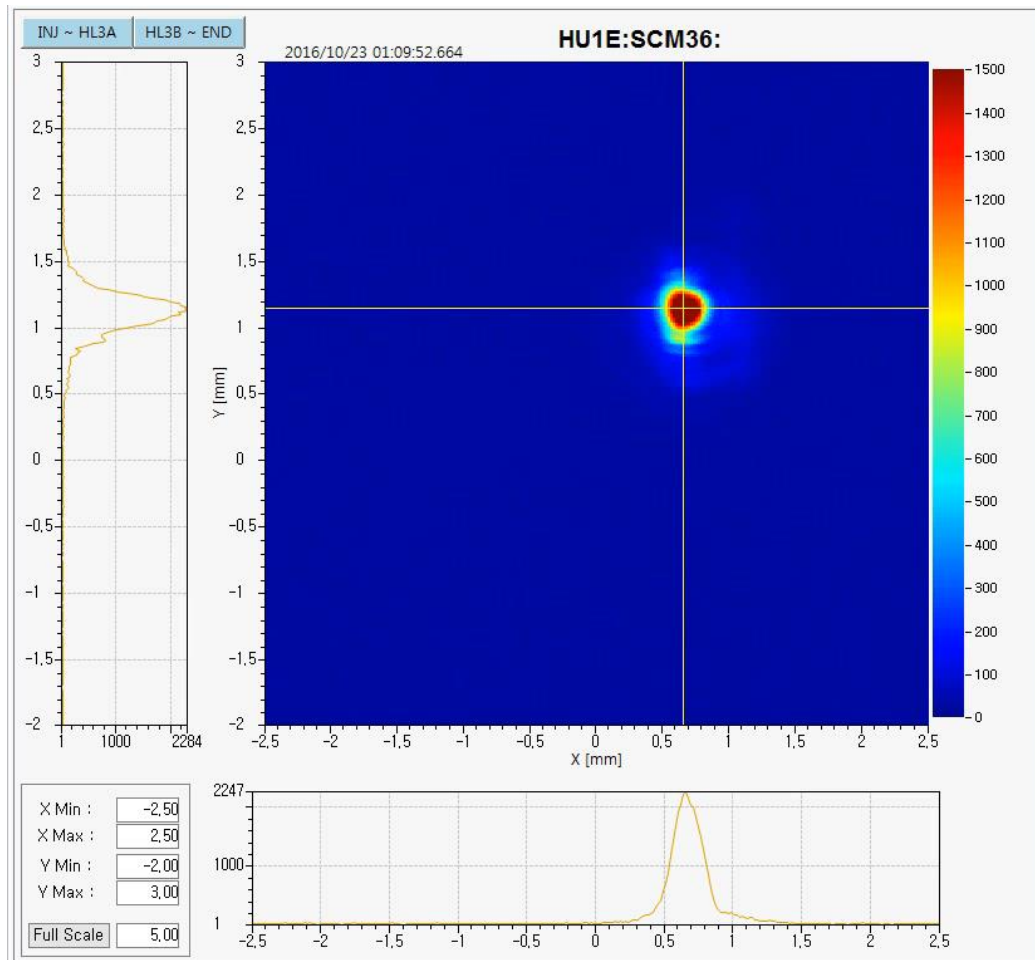


0.2 nm FEL (16 Oct. 2016, 1:22 am)

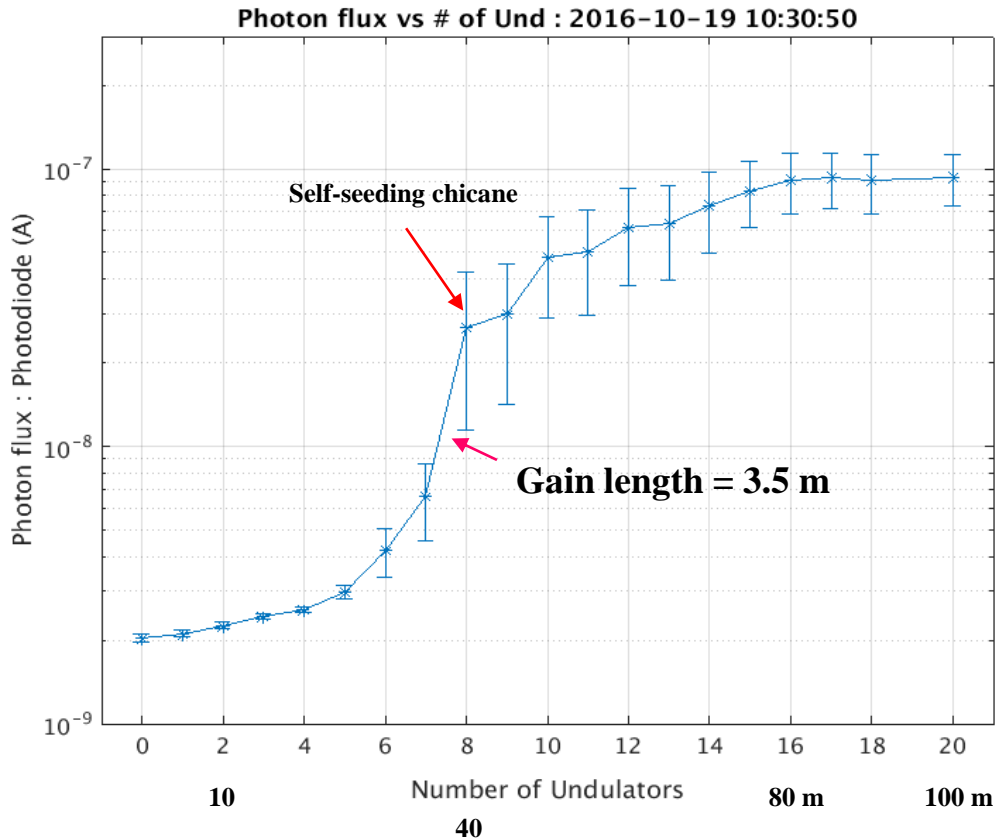
- Beam energy: 6.7 GeV
- Undulator gap: 9 mm
- Undulator K: 1.87
- Number of undulators: 20
- K-tuning & Phase-matching data are applied



Movie of 0.2 nm FEL

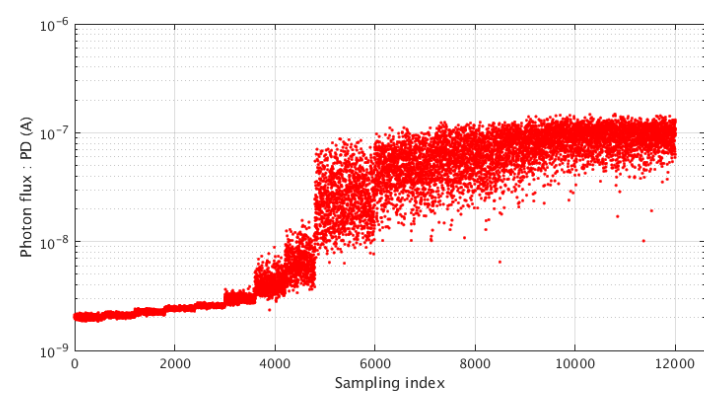
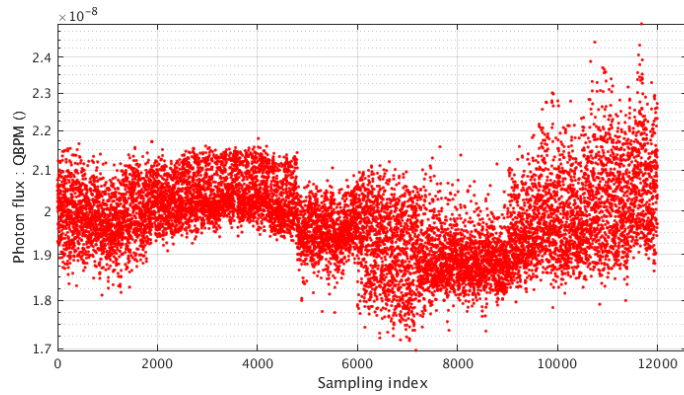
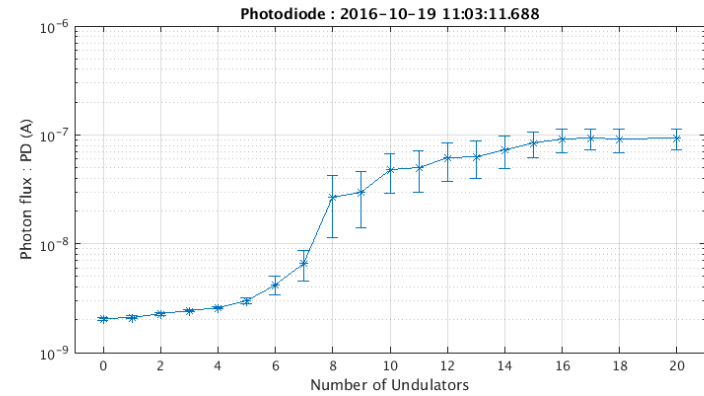
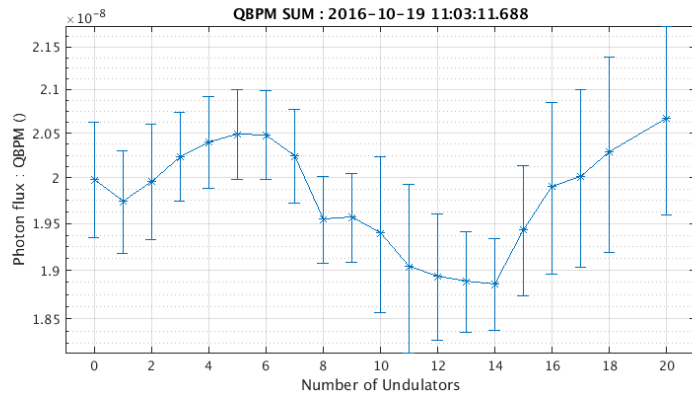


Saturation of 0.2 nm FEL



- ✓ **Preliminary measurement** with a photo-diode & DCM
- ✓ Same **K** for all undulators
- ✓ No substantial increase after Self-Seeding Chicane
- ✓ **FEL is saturated?**

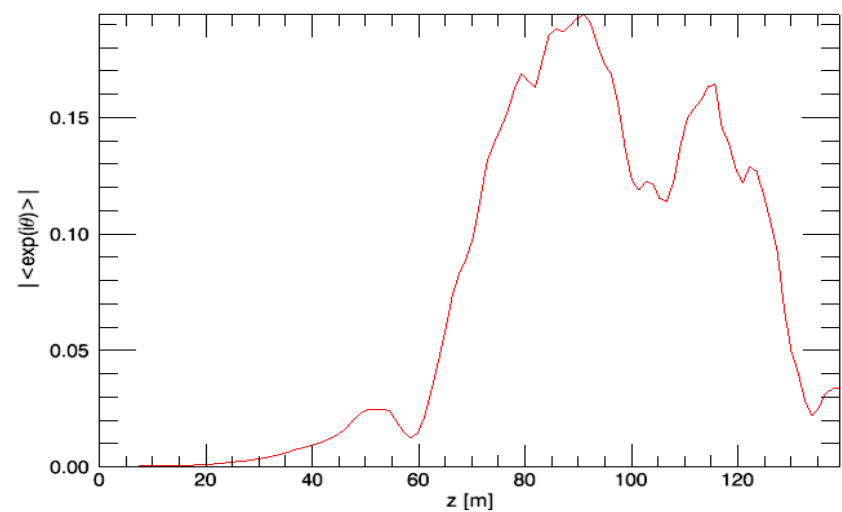
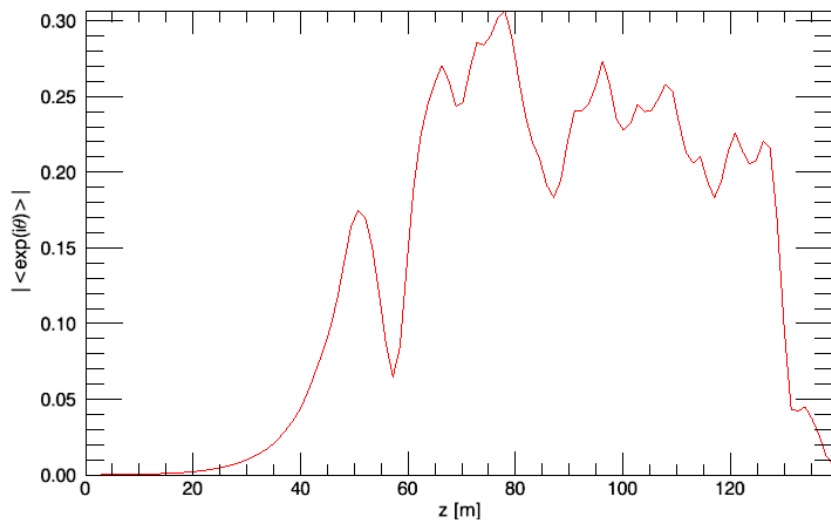
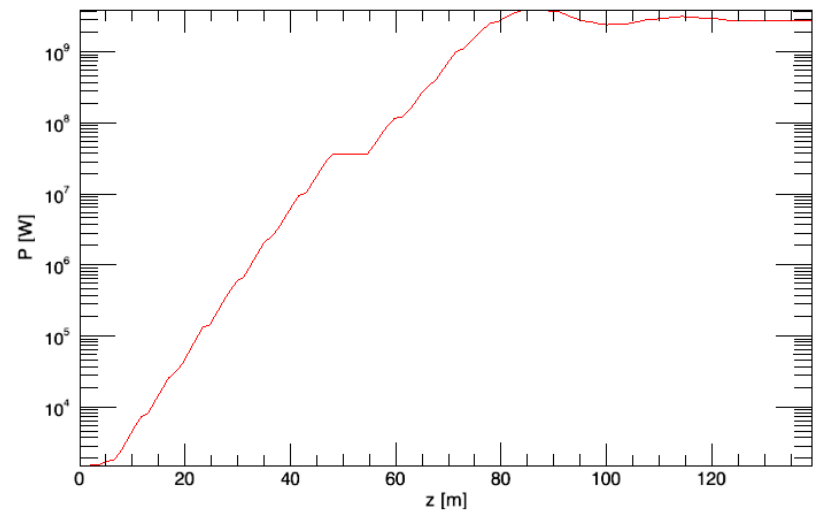
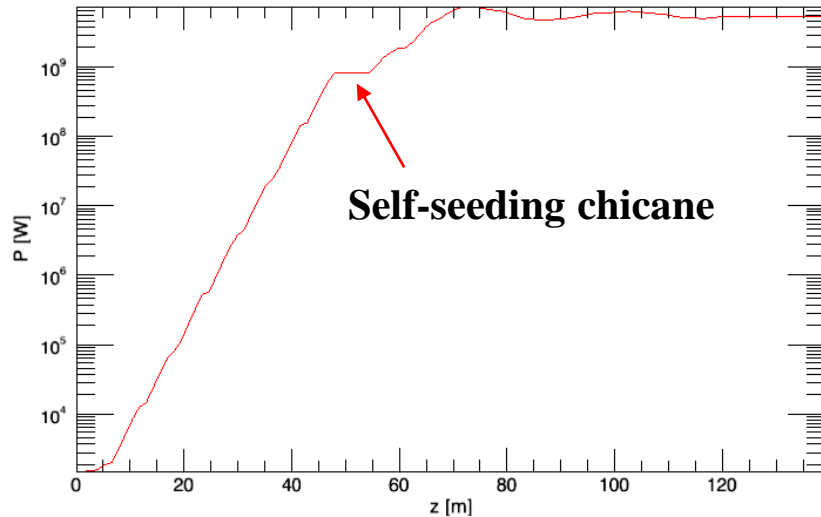




Genesis Simulation for 0.2 nm

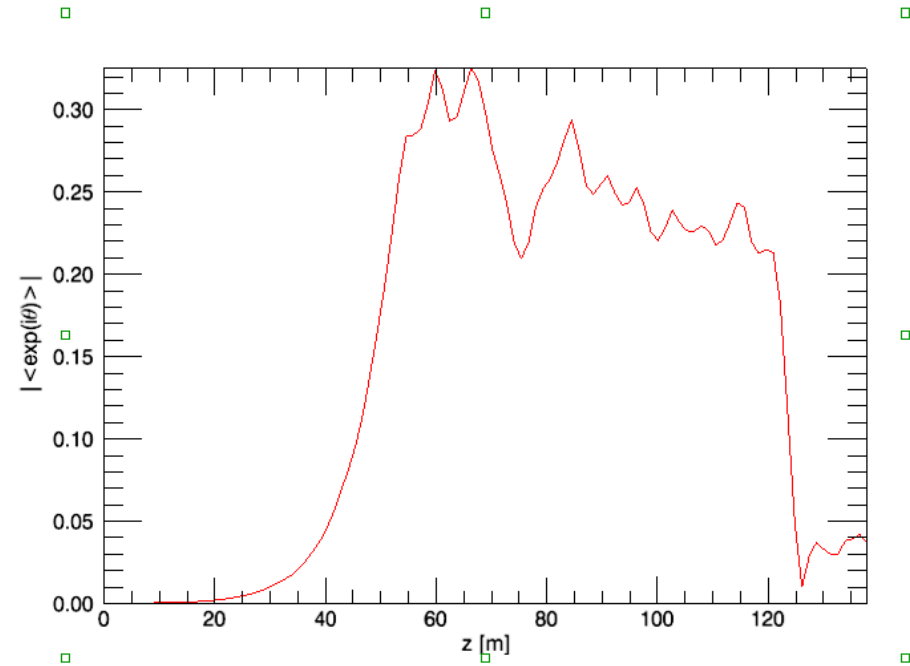
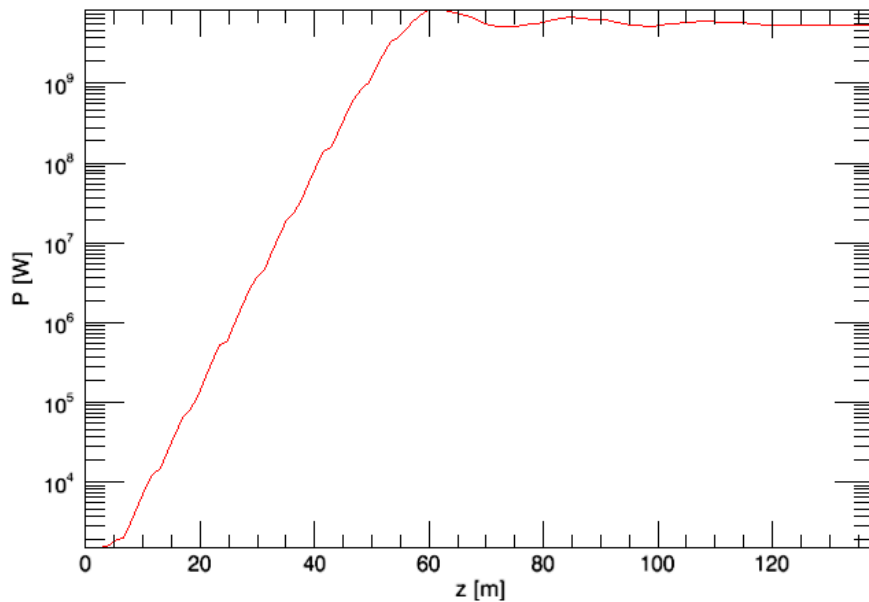
- Emittance (slice): 0.6 μm
- Peak current : 3 kA

- Emittance (slice): 0.9 μm
- Peak current : 3 kA



Genesis Simulation for 0.2 nm w/o self-seeding

- Emittance (slice): 0.6 μm
- Peak current : 3 kA

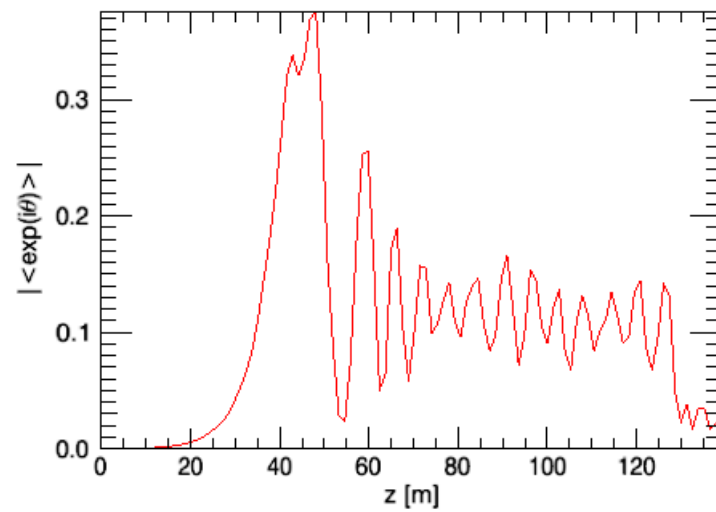
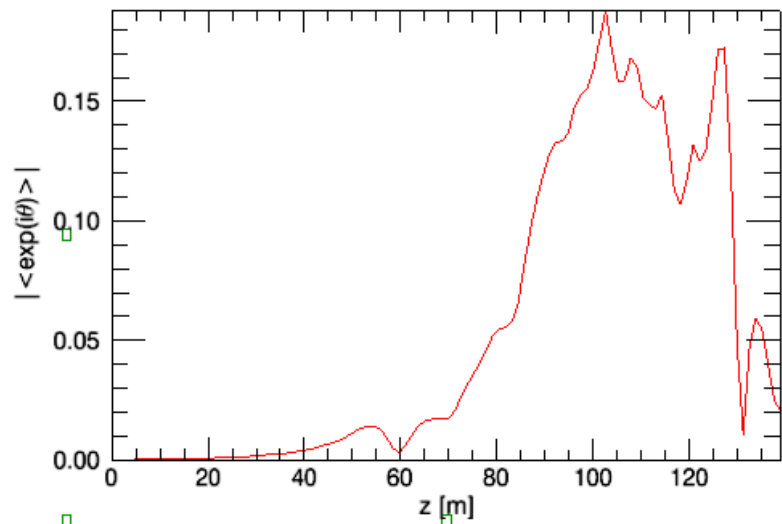
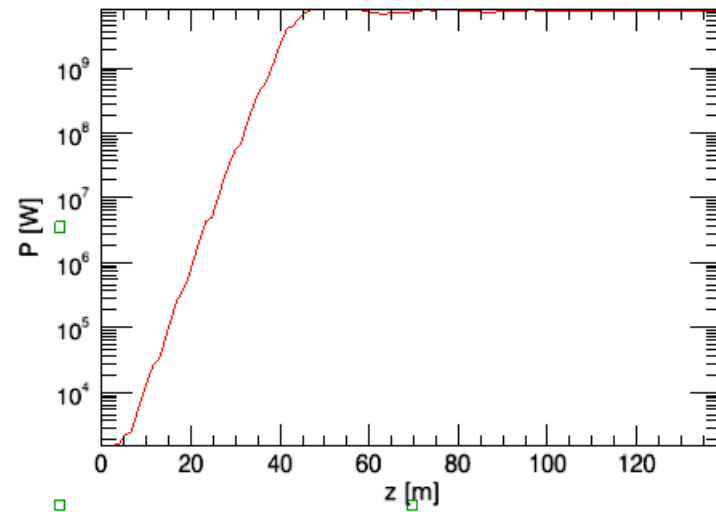
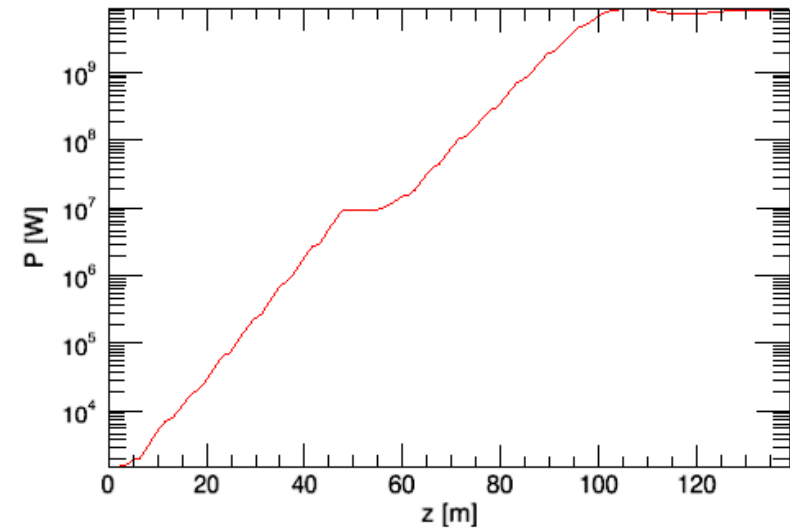


Genesis for 0.15 nm & 0.35 nm

■ 0.15 nm

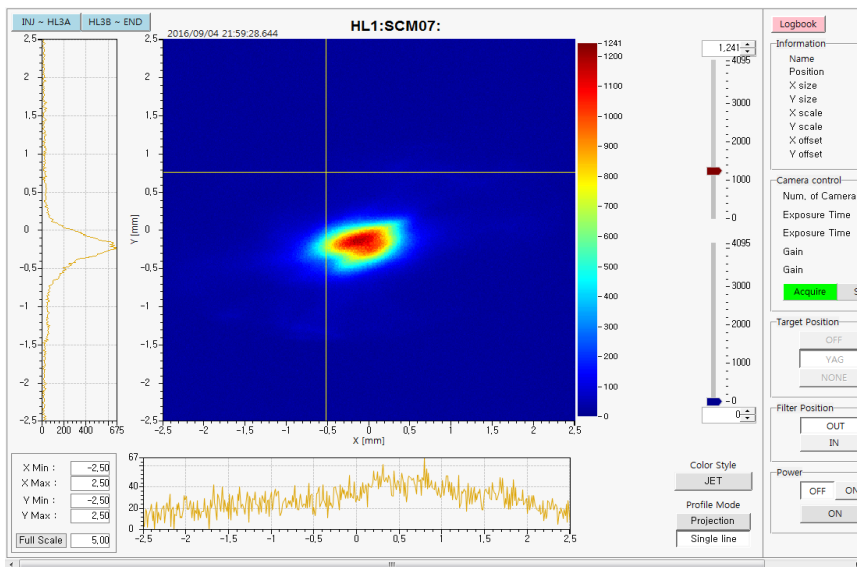
- Emittance (slice): 0.6 μm
- Peak current : 3 kA

■ 0.35 nm

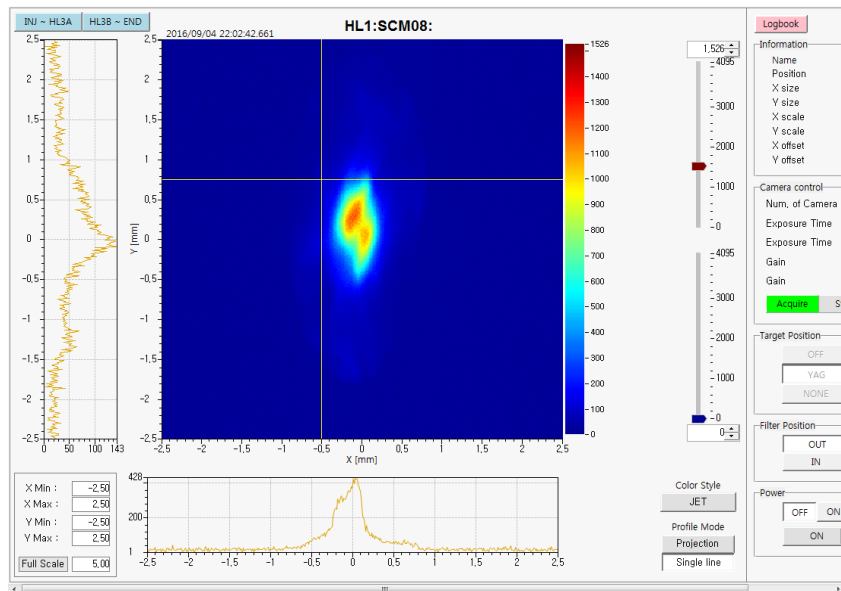


- ✓ Factors to be considered as FEL Intensity Limitation
 - 1) **Vertical emittance growth**
 - dispersion at L1 & L2 → Redo the Linac BBA is necessary
 - twin beam from laser → Replacement of bad optics components
 - 2) **Emittance growth due to strong CSR**
 - Currently overcome by BC2 collimator
 - Need to decrease Compression Ratio at BC2 by decreasing the laser pulse length
 - Or, to use three Bunch compressors
 - 3) **poor betatron matching to undulators**
 - Undulator matching program is being prepared.
 - Four Wire scanners along the undulators were tested to find detector saturation → Detector to be improved for e-beam profile measurement
 - 4) **Correlated energy spread is too big (10⁻³).** Chirp needs to be compensated.
 - 5) **Halo particles generated at the gun and laser**
 - Decrease to gun phase to -30 or below
 - Improve the uniformity of laser profile

Vertical emittance growth



- ✓ Due to dispersion and **twin beam**
- ✓ Twin beam is generated at the gun.



- Strongly depend on the cathode position of laser beam
- It is thought due to degradation of optics from Laser system to Gun
- To be improved soon

Summary

- 0.2 nm FEL lasing is achieved.
- Procedures for Undulator BBA, K-value tuning, undulator field centre, and phase matching are established.
- The saturation of 0.2 nm FEL is also achieved.
- An X-band deflector is absolutely necessary!!

Thank you for your attention

